

LMV3xxA Low-Voltage Rail-to-Rail Output Operational Amplifiers

1 Features

- Low input offset voltage: ± 1 mV
- Rail-to-rail output
- Unity-gain bandwidth: 1 MHz
- Low broadband noise: $30 \text{ nV}/\sqrt{\text{Hz}}$
- Low input bias current: 10 pA
- Low quiescent current: 70 $\mu\text{A}/\text{Ch}$
- Unity-gain stable
- Internal RFI and EMI filter
- Operational at supply voltages as low as 2.5 V
- Easier to stabilize with higher capacitive load due to resistive open-loop output impedance
- Extended temperature range: -40°C to 125°C

2 Applications

- Smoke detectors
- Motion detectors
- Wearable devices
- Large and small appliances
- EPOS
- Barcode scanners
- Sensor signal conditioning
- Power modules
- Personal electronics
- Active filters
- HVAC: heating, ventilating, and air conditioning
- Motor control: AC induction
- Low-side current sensing

3 Description

The LMV3xxA family includes single - (LMV321A), dual - (LMV358A), and quad-channel (LMV324A) low-voltage (2.5 V to 5.5 V) operational amplifiers (op amps) with rail-to-rail output swing capabilities. These op amps provide a cost-effective solution for space-constrained applications such as large appliances, smoke detectors, and personal electronics where low-voltage operation and high capacitive-load drive are required. The capacitive-load drive of the LMV3xxA family is 500 pF, and the resistive open-loop output impedance makes stabilization easier with much higher capacitive loads. These op amps are designed specifically for low-voltage operation (2.5 V to 5.5 V) with performance specifications similar to the LMV3xx devices.

The robust design of the LMV3xxA family simplifies circuit design. The op amps feature unity-gain stability, an integrated RFI and EMI rejection filter, and no-phase reversal in overdrive conditions.

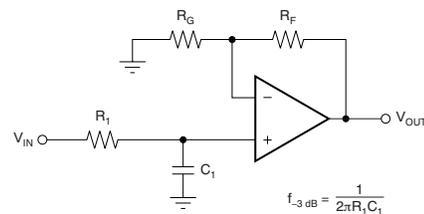
The LMV3xxA family is available in industry-standard packages such as SOIC, MSOP, SOT-23, and TSSOP packages.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|------------|-------------------|
| LMV321A | SOT-23 (5) | 1.60 mm x 2.90 mm |
| | SC70 (5) | 1.25 mm x 2.00 mm |
| LMV358A | SOIC (8) | 3.91 mm x 4.90 mm |
| | TSSOP (8) | 3.00 mm x 4.40 mm |
| | SOT-23 (8) | 1.60 mm x 2.90 mm |
| | VSSOP (8) | 3.00 mm x 3.00 mm |
| LMV324A | SOIC (14) | 8.65 mm x 3.91 mm |
| | TSSOP (14) | 4.40 mm x 5.00 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Single-Pole, Low-Pass Filter



$$f_{-3 \text{ dB}} = \frac{1}{2\pi R_1 C_1}$$

$$\frac{V_{\text{OUT}}}{V_{\text{IN}}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1 C_1}\right)$$



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (September 2019) to Revision F Page

- Added SOT-23 (U) package information to *Pin Configuration and Functions* section..... **4**

Changes from Revision D (November 2018) to Revision E Page

- Added SOT-23 (8) package to *Device Information*
- Added SOT-23 (8) (DDF) package to the *Pin Configuration and Functions* section.....
- Added DDF (SOT-23) package to *Thermal Information: LMV358A*.....

Changes from Revision C (August 2018) to Revision D Page

- Changed the document status From: Production Data/Mixed To: Production Data
- Changed LMV321A SOT-23 and SC70 packages From: Preview To: Production
- Changed LMV324A SOIC and TSSOP packages From: Preview To: Production.....
- Deleted DBV (SOT-23) and DCK (SC70) package preview note from the LM321A *Thermal Information* table
- Deleted D (SOIC) and PW (TSSOP) package preview note from the LM324A *Thermal Information* table

Changes from Revision B (June 2018) to Revision C Page

- Changed Typical Iq feature from 80 μ A/Ch to 70 μ A/Ch.....
- Changed typical Iq from 80 μ A to 70 μ A

Changes from Revision A (May 2018) to Revision B
Page

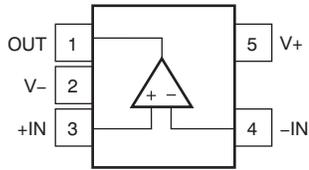
| | |
|---|---|
| • Added SOT-23 package to <i>Device Information</i> table | 1 |
| • Added SC70 package to <i>Device Information</i> table | 1 |
| • Added TSSOP-8 package to <i>Device Information</i> table | 1 |
| • Added SOIC-14 package to <i>Device Information</i> table | 1 |
| • Added TSSOP-14 package to <i>Device Information</i> table | 1 |
| • Added <i>Thermal Information: LMV321A</i> | 7 |
| • Added <i>Thermal Information: LMV324A</i> | 7 |

Changes from Original (December 2017) to Revision A
Page

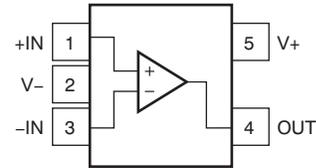
| | |
|---|---|
| • Changed device status from Advance Information to Production Data/Mixed Status..... | 1 |
| • Added DGK and PW package to the LMV358A <i>Thermal Information</i> table | 7 |

5 Pin Configuration and Functions

LMV321A DBV Package
5-Pin SOT-23
Top View



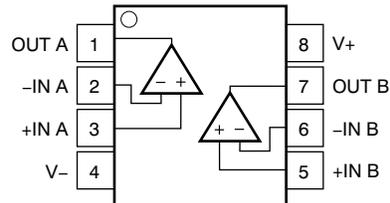
LMV321A DCK, LMV321AU DBV Package
5-Pin SC70, SOT-23
Top View



Pin Functions: LMV321A

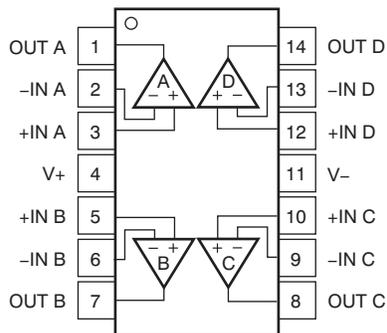
| NAME | PIN | | I/O | DESCRIPTION |
|------|-----|--------------|-----|--|
| | DBV | DCK, DBV (U) | | |
| -IN | 4 | 3 | I | Inverting input |
| +IN | 3 | 1 | I | Noninverting input |
| OUT | 1 | 4 | O | Output |
| V- | 2 | 2 | — | Negative (lowest) supply or ground (for single-supply operation) |
| V+ | 5 | 5 | — | Positive (highest) supply |

LMV358A D, DDF, DGK, PW Packages
8-Pin SOIC, VSSOP, TSSOP
Top View



Pin Functions: LMV358A

| NAME | PIN | | I/O | DESCRIPTION |
|-------|-----|--|-----|--|
| | NO. | | | |
| -IN A | 2 | | I | Inverting input, channel A |
| +IN A | 3 | | I | Noninverting input, channel A |
| -IN B | 6 | | I | Inverting input, channel B |
| +IN B | 5 | | I | Noninverting input, channel B |
| OUT A | 1 | | O | Output, channel A |
| OUT B | 7 | | O | Output, channel B |
| V- | 4 | | — | Negative (lowest) supply or ground (for single-supply operation) |
| V+ | 8 | | — | Positive (highest) supply |

**LMV324A D, PW Packages
14-Pin SOIC, TSSOP
Top View**

Pin Functions: LMV324A

| PIN | | I/O | DESCRIPTION |
|-------|-----|-----|--|
| NAME | NO. | | |
| -IN A | 2 | I | Inverting input, channel A |
| +IN A | 3 | I | Noninverting input, channel A |
| -IN B | 6 | I | Inverting input, channel B |
| +IN B | 5 | I | Noninverting input, channel B |
| -IN C | 9 | I | Inverting input, channel C |
| +IN C | 10 | I | Noninverting input, channel C |
| -IN D | 13 | I | Inverting input, channel D |
| +IN D | 12 | I | Noninverting input, channel D |
| OUT A | 1 | O | Output, channel A |
| OUT B | 7 | O | Output, channel B |
| OUT C | 8 | O | Output, channel C |
| OUT D | 14 | O | Output, channel D |
| V- | 11 | — | Negative (lowest) supply or ground (for single-supply operation) |
| V+ | 4 | — | Positive (highest) supply |

6 Specifications

6.1 Absolute Maximum Ratings

 over operating temperature range (unless otherwise noted)⁽¹⁾

| | | MIN | MAX | UNIT | |
|---------------------------------------|------------------------|--------------|-------------------|------------|---|
| Supply voltage, ($[V+] - [V-]$) | | 0 | 6 | V | |
| Signal input pins | Voltage ⁽²⁾ | Common-mode | (V-) – 0.5 | (V+) + 0.5 | V |
| | | Differential | (V+) – (V-) + 0.2 | | V |
| | Current ⁽²⁾ | –10 | 10 | mA | |
| Output short-circuit ⁽³⁾ | | Continuous | | | |
| Operating, T_A | | –55 | 150 | °C | |
| Operating junction temperature, T_J | | | 150 | °C | |
| Storage temperature, T_{stg} | | –65 | 150 | °C | |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.
- (3) Short-circuit to ground, one amplifier per package.

6.2 ESD Ratings

| | | VALUE | UNIT |
|-------------|-------------------------|--|-------|
| $V_{(ESD)}$ | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 |
| | | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±1000 |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|-------|-----------------------|-----|-----|------|
| V_S | Supply voltage | 2.5 | 5.5 | V |
| T_A | Specified temperature | –40 | 125 | °C |

6.4 Thermal Information: LMV321A

| THERMAL METRIC ⁽¹⁾ | | LMV321A | | UNIT |
|-------------------------------|--|--------------|------------|------|
| | | DBV (SOT-23) | DCK (SC70) | |
| | | 5 PINS | 5 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 232.8 | 239.6 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 153.8 | 148.5 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 100.9 | 82.3 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 77.2 | 54.5 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 100.4 | 81.8 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | N/A | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).

6.5 Thermal Information: LMV358A

| THERMAL METRIC ⁽¹⁾ | | LMV358A | | | | UNIT |
|-------------------------------|--|----------|-------------|------------|--------------|------|
| | | D (SOIC) | DGK (VSSOP) | PW (TSSOP) | DDF (SOT-23) | |
| | | 8 PINS | 8 PINS | 8 PINS | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 147.4 | 201.2 | 205.8 | 183.7 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 94.3 | 85.7 | 106.7 | 112.5 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 89.5 | 122.9 | 133.9 | 98.2 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 47.3 | 21.2 | 34.4 | 18.8 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 89 | 121.4 | 132.6 | 97.6 | °C/W |

(1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).

6.6 Thermal Information: LMV324A

| THERMAL METRIC ⁽¹⁾ | | LMV324A | | UNIT |
|-------------------------------|--|----------|------------|------|
| | | D (SOIC) | PW (TSSOP) | |
| | | 14 PINS | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 102.1 | 148.3 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 56.8 | 68.1 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 58.5 | 92.7 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 20.5 | 16.9 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 58.1 | 91.8 | °C/W |

(1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).

6.7 Electrical Characteristics

For $V_S = (V_+) - (V_-) = 2.5\text{ V to }5.5\text{ V}$ ($\pm 0.9\text{ V to } \pm 2.75\text{ V}$), $T_A = 25^\circ\text{C}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, and $V_{CM} = V_{OUT} = V_S / 2$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------|--|---|--------------------|----------|--------------------|------------------------------|
| OFFSET VOLTAGE | | | | | | |
| V_{OS} | Input offset voltage | $V_S = 5\text{ V}$ | | ± 1 | ± 4 | mV |
| | | $V_S = 5\text{ V}$, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ | | | ± 5 | |
| dV_{OS}/dT | V_{OS} vs temperature | $T_A = -40^\circ\text{C to }125^\circ\text{C}$ | | ± 1 | | $\mu\text{V}/^\circ\text{C}$ |
| PSRR | Power-supply rejection ratio | $V_S = 2.5\text{ to }5.5\text{ V}$, $V_{CM} = (V_-)$ | 78 | 100 | | dB |
| INPUT VOLTAGE RANGE | | | | | | |
| V_{CM} | Common-mode voltage range | No phase reversal, rail-to-rail input | $(V_-) - 0.1$ | | $(V_+) - 1$ | V |
| CMRR | Common-mode rejection ratio | $V_S = 2.5\text{ V}$, $(V_-) - 0.1\text{ V} < V_{CM} < (V_+) - 1.4\text{ V}$ $T_A = -40^\circ\text{C to }125^\circ\text{C}$ | | 86 | | dB |
| | | $V_S = 5.5\text{ V}$, $(V_-) - 0.1\text{ V} < V_{CM} < (V_+) - 1.4\text{ V}$ $T_A = -40^\circ\text{C to }125^\circ\text{C}$ | | 95 | | |
| | | $V_S = 5.5\text{ V}$, $(V_-) - 0.1\text{ V} < V_{CM} < (V_+) + 0.1\text{ V}$ $T_A = -40^\circ\text{C to }125^\circ\text{C}$ | 63 | 77 | | |
| | | $V_S = 2.5\text{ V}$, $(V_-) - 0.1\text{ V} < V_{CM} < (V_+) + 0.1\text{ V}$ $T_A = -40^\circ\text{C to }125^\circ\text{C}$ | | 68 | | |
| INPUT BIAS CURRENT | | | | | | |
| I_B | Input bias current | $V_S = 5\text{ V}$ | | ± 10 | | pA |
| I_{OS} | Input offset current | | | ± 3 | | pA |
| NOISE | | | | | | |
| E_n | Input voltage noise (peak-to-peak) | $f = 0.1\text{ Hz to }10\text{ Hz}$, $V_S = 5\text{ V}$ | | 5.1 | | μV_{PP} |
| e_n | Input voltage noise density | $f = 1\text{ kHz}$, $V_S = 5\text{ V}$ | | 33 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| | | $f = 10\text{ kHz}$, $V_S = 5\text{ V}$ | | 30 | | |
| i_n | Input current noise density | $f = 1\text{ kHz}$, $V_S = 5\text{ V}$ | | 25 | | $\text{fA}/\sqrt{\text{Hz}}$ |
| INPUT CAPACITANCE | | | | | | |
| C_{ID} | Differential | | | 1.5 | | pF |
| C_{IC} | Common-mode | | | 5 | | pF |
| OPEN-LOOP GAIN | | | | | | |
| A_{OL} | Open-loop voltage gain | $V_S = 5.5\text{ V}$, $(V_-) + 0.05\text{ V} < V_O < (V_+) - 0.05\text{ V}$, $R_L = 10\text{ k}\Omega$ | 100 | 115 | | dB |
| | | $V_S = 2.5\text{ V}$, $(V_-) + 0.04\text{ V} < V_O < (V_+) - 0.04\text{ V}$, $R_L = 10\text{ k}\Omega$ | | 98 | | |
| | | $V_S = 2.5\text{ V}$, $(V_-) + 0.1\text{ V} < V_O < (V_+) - 0.1\text{ V}$, $R_L = 2\text{ k}\Omega$ | | 112 | | |
| | | $V_S = 5.5\text{ V}$, $(V_-) + 0.15\text{ V} < V_O < (V_+) - 0.15\text{ V}$, $R_L = 2\text{ k}\Omega$ | | 128 | | |
| FREQUENCY RESPONSE | | | | | | |
| GBW | Gain-bandwidth product | $V_S = 5\text{ V}$ | | 1 | | MHz |
| ϕ_m | Phase margin | $V_S = 5.5\text{ V}$, $G = 1$ | | 76 | | ° |
| SR | Slew rate | $V_S = 5\text{ V}$ | | 1.7 | | V/ μs |
| t_s | Settling time | To 0.1%, $V_S = 5\text{ V}$, 2-V step, $G = +1$, $C_L = 100\text{ pF}$ | | 3 | | μs |
| | | To 0.01%, $V_S = 5\text{ V}$, 2-V step, $G = +1$, $C_L = 100\text{ pF}$ | | 4 | | |
| t_{OR} | Overload recovery time | $V_S = 5\text{ V}$, $V_{IN} \times \text{gain} > V_S$ | | 0.9 | | μs |
| THD+N | Total harmonic distortion + noise | $V_S = 5.5\text{ V}$, $V_{CM} = 2.5\text{ V}$, $V_O = 1\text{ V}_{RMS}$, $G = +1$, $f = 1\text{ kHz}$, 80-kHz measurement BW | | 0.005% | | |
| OUTPUT | | | | | | |
| V_O | Voltage output swing from supply rails | $V_S = 5.5\text{ V}$, $R_L = 10\text{ k}\Omega$ | | 20 | 50 | mV |
| | | $V_S = 5.5\text{ V}$, $R_L = 2\text{ k}\Omega$ | | 40 | 75 | |
| I_{SC} | Short-circuit current | $V_S = 5.5\text{ V}$ | | ± 40 | | mA |
| Z_O | Open-loop output impedance | $V_S = 5\text{ V}$, $f = 1\text{ MHz}$ | | 1200 | | Ω |
| POWER SUPPLY | | | | | | |
| V_S | Specified voltage range | | 2.5 (± 1.25) | | 5.5 (± 2.75) | V |
| I_Q | Quiescent current per amplifier | $I_O = 0\text{ mA}$, $V_S = 5.5\text{ V}$ | | 70 | 125 | μA |
| | | $I_O = 0\text{ mA}$, $V_S = 5.5\text{ V}$, $T_A = -40^\circ\text{C to }125^\circ\text{C}$ | | | 150 | |
| | Power-on time | $V_S = 0\text{ V to }5\text{ V}$, to 90% I_Q level | | 50 | | μs |

6.8 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_+ = 2.75\text{ V}$, $V_- = -2.75\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

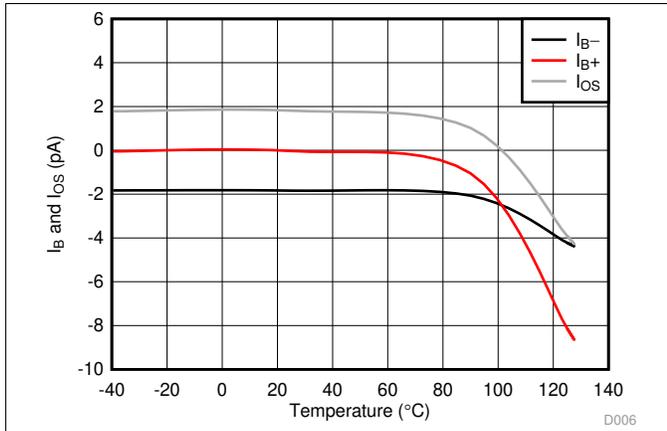


Figure 1. I_B and I_{OS} vs Temperature

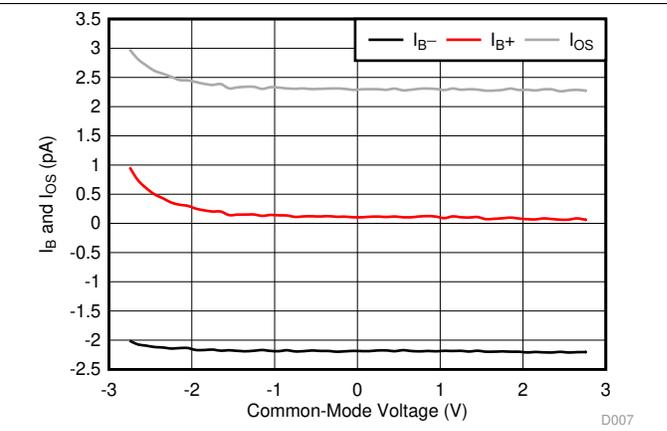


Figure 2. I_B and I_{OS} vs Common-Mode Voltage

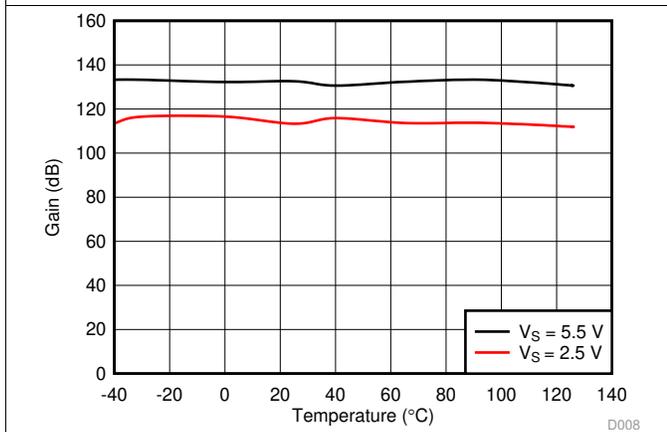


Figure 3. Open-Loop Gain vs Temperature

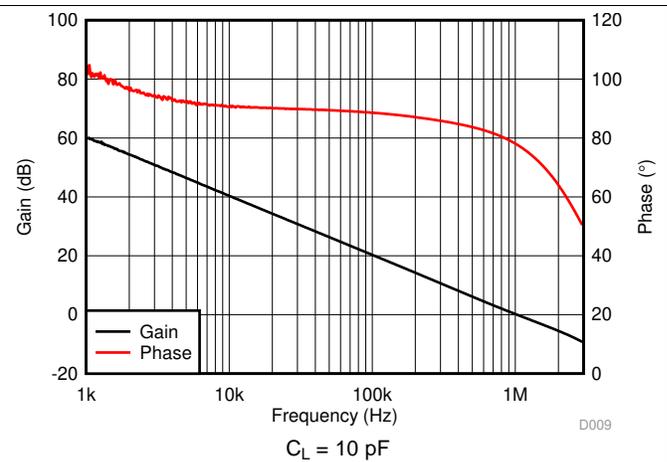


Figure 4. Open-Loop Gain and Phase vs Frequency

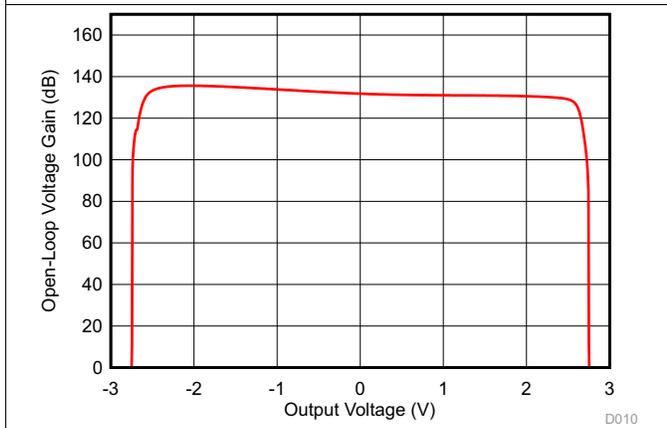


Figure 5. Open-Loop Gain vs Output Voltage

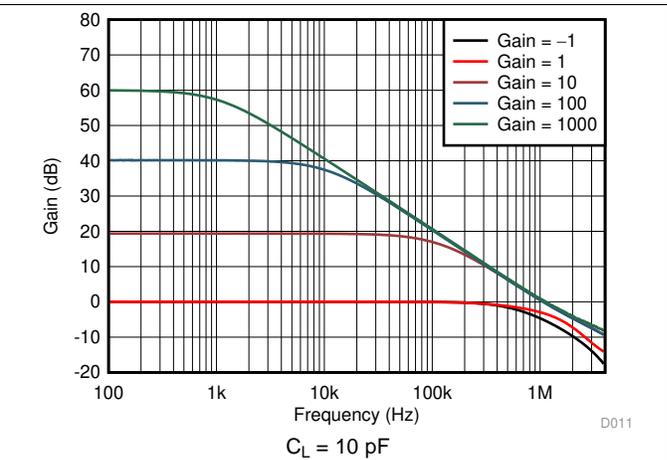


Figure 6. Closed-Loop Gain vs Frequency

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_+ = 2.75\text{ V}$, $V_- = -2.75\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

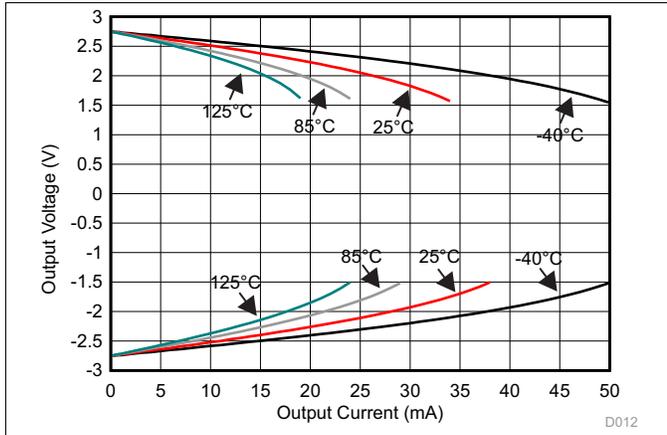


Figure 7. Output Voltage vs Output Current (Claw)

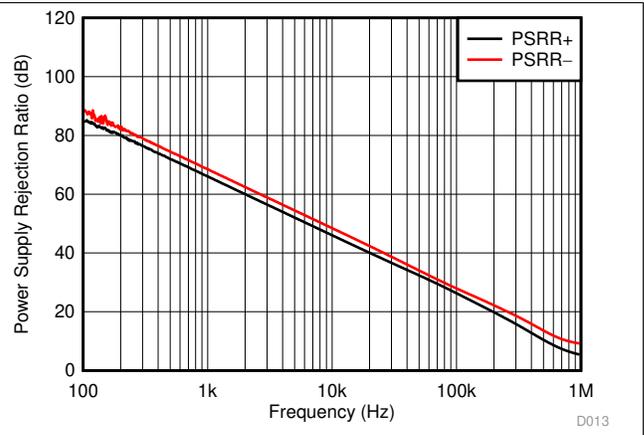


Figure 8. PSRR vs Frequency

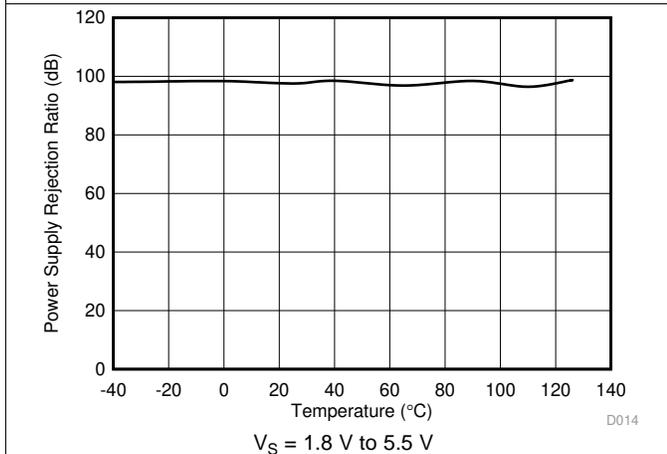


Figure 9. DC PSRR vs Temperature

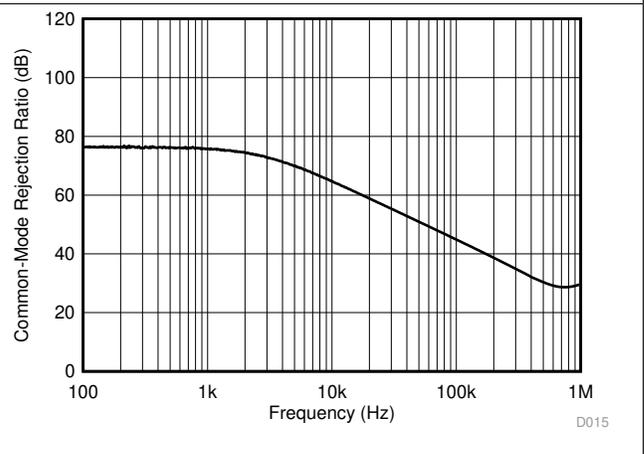


Figure 10. CMRR vs Frequency

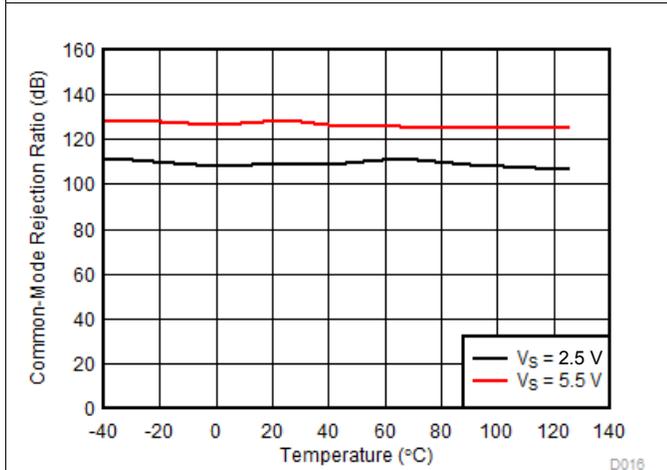


Figure 11. DC CMRR vs Temperature

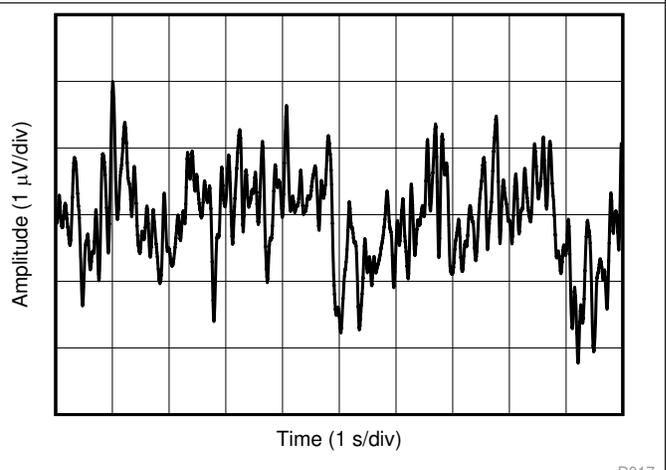


Figure 12. 0.1 Hz to 10 Hz Integrated Voltage Noise

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_+ = 2.75\text{ V}$, $V_- = -2.75\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

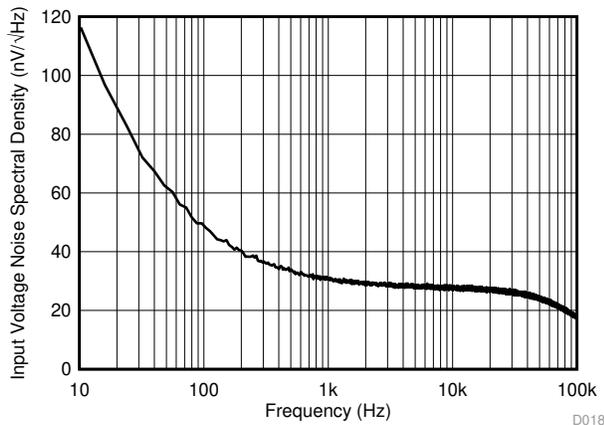
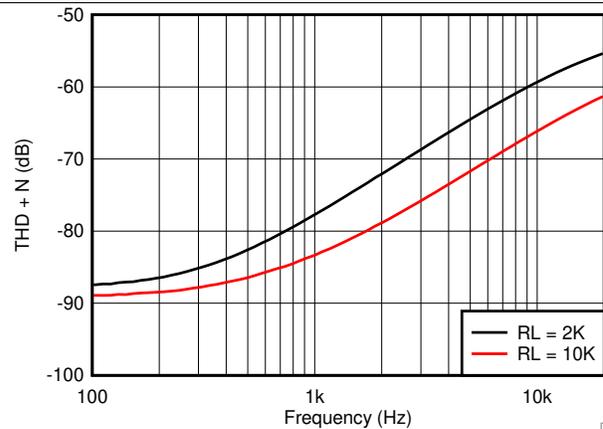
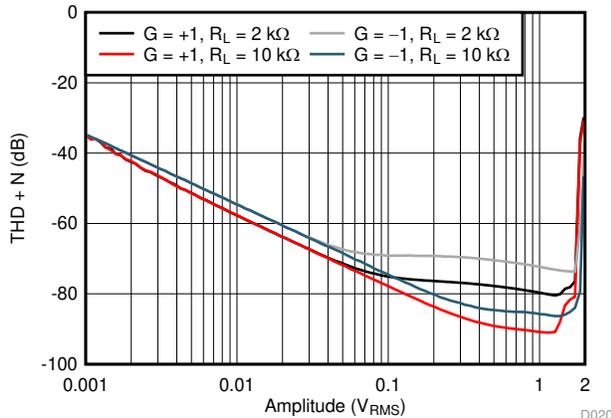


Figure 13. Input Voltage Noise Spectral Density



$V_S = 5.5\text{ V}$, $V_{CM} = 2.5\text{ V}$, $G = 1$, $BW = 80\text{ kHz}$, $V_{OUT} = 0.5\text{ V}_{RMS}$

Figure 14. THD + N vs Frequency



$V_S = 5.5\text{ V}$, $V_{CM} = 2.5\text{ V}$, $f = 1\text{ kHz}$, $G = 1$, $BW = 80\text{ kHz}$

Figure 15. THD + N vs Amplitude

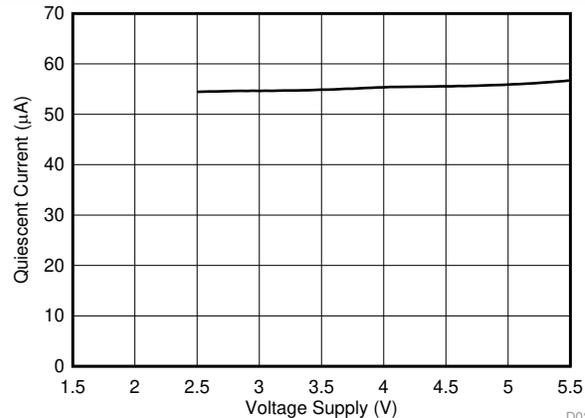


Figure 16. Quiescent Current vs Supply Voltage

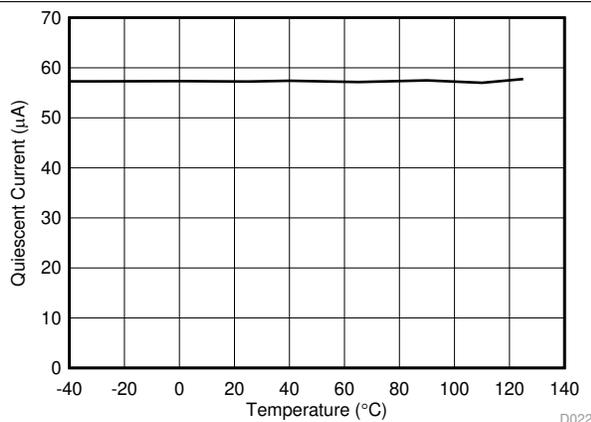


Figure 17. Quiescent Current vs Temperature

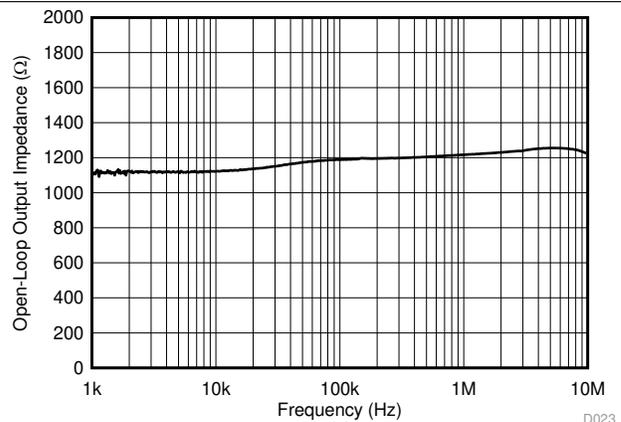


Figure 18. Open-Loop Output Impedance vs Frequency

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_+ = 2.75\text{ V}$, $V_- = -2.75\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

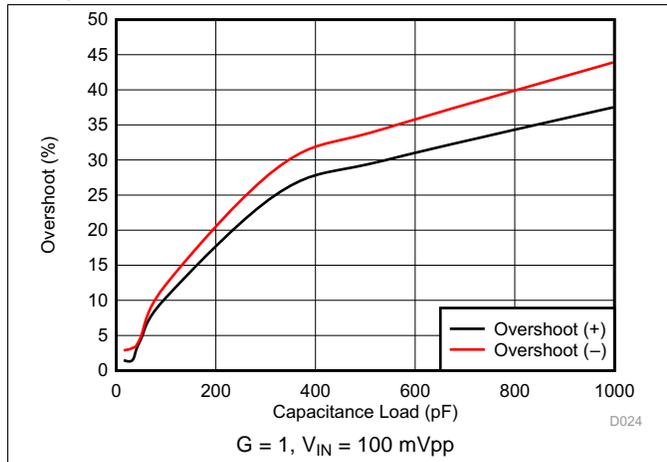


Figure 19. Small Signal Overshoot vs Capacitive Load

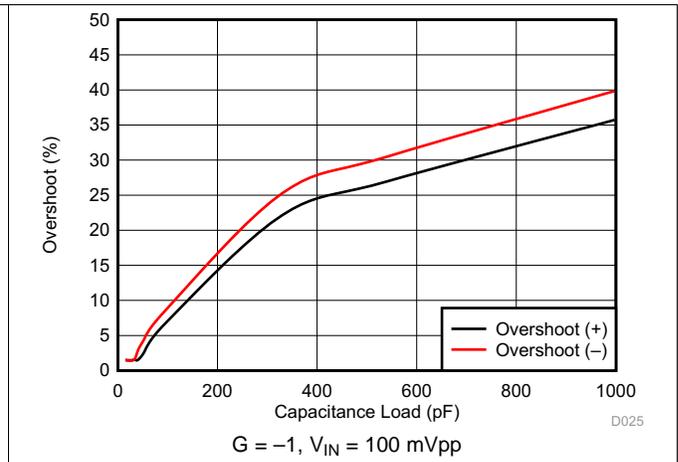


Figure 20. Small Signal Overshoot vs Capacitive Load

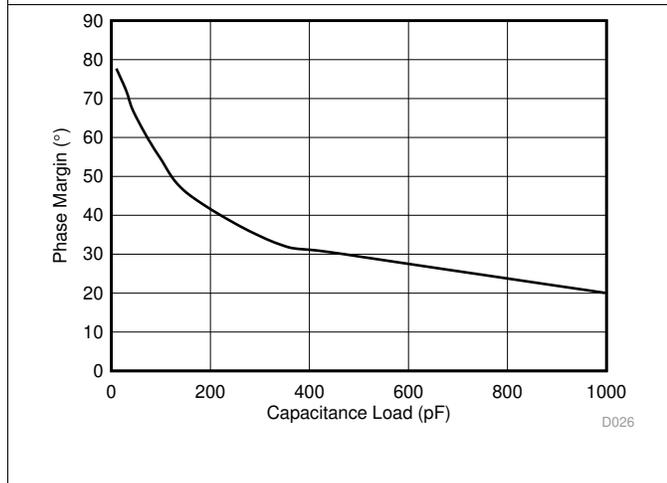


Figure 21. Phase Margin vs Capacitive Load

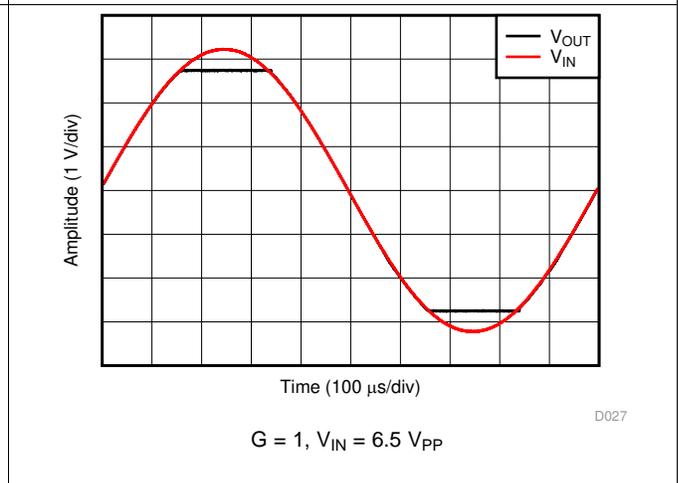


Figure 22. No Phase Reversal

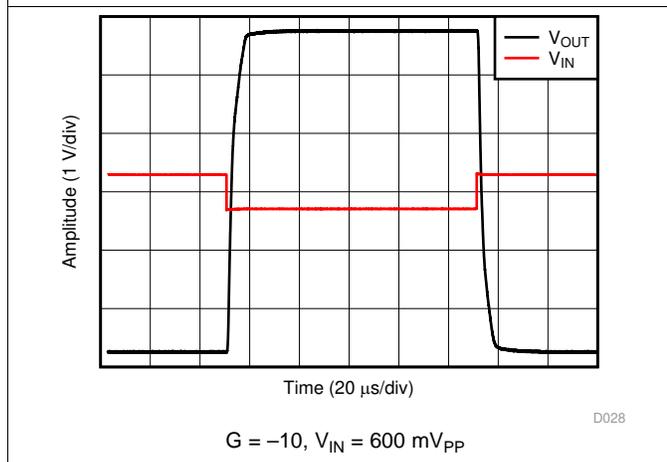


Figure 23. Overload Recovery

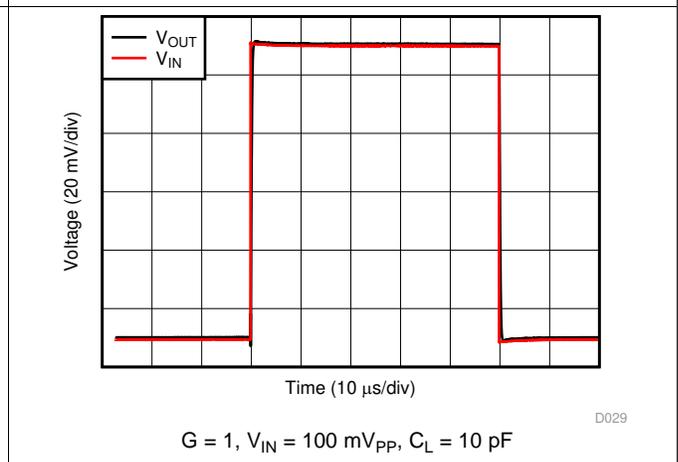


Figure 24. Small-Signal Step Response

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_+ = 2.75\text{ V}$, $V_- = -2.75\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

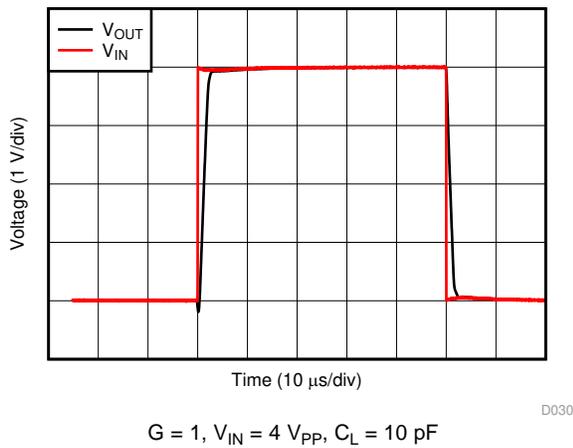


Figure 25. Large-Signal Step Response

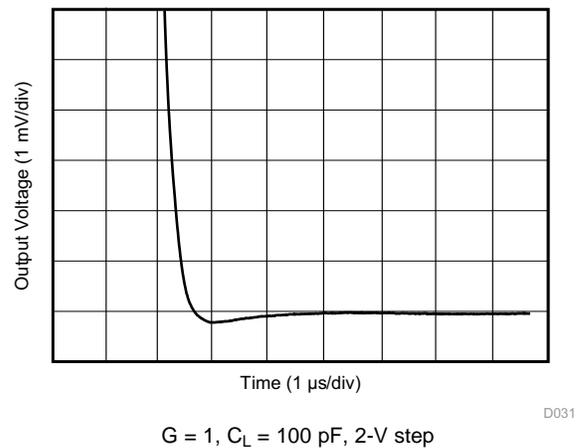


Figure 26. Large-Signal Settling Time (Negative)

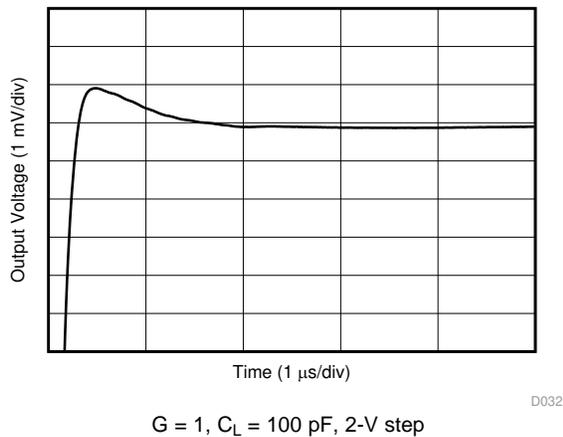


Figure 27. Large-Signal Settling Time (Positive)

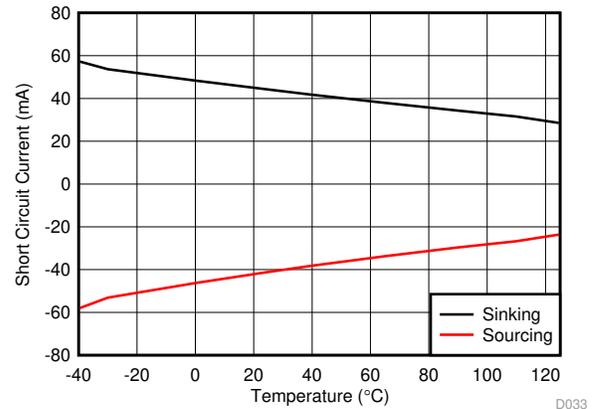


Figure 28. Short-Circuit Current vs Temperature

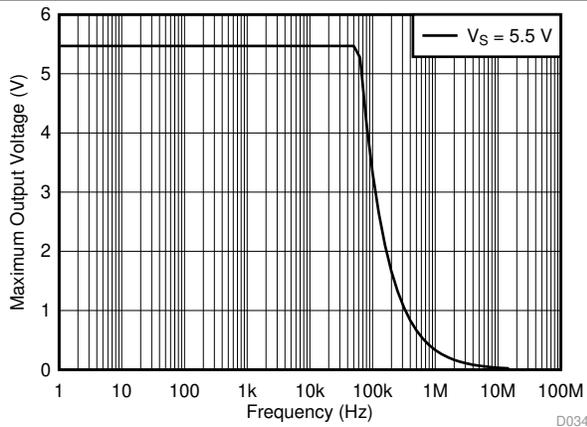


Figure 29. Maximum Output Voltage vs Frequency

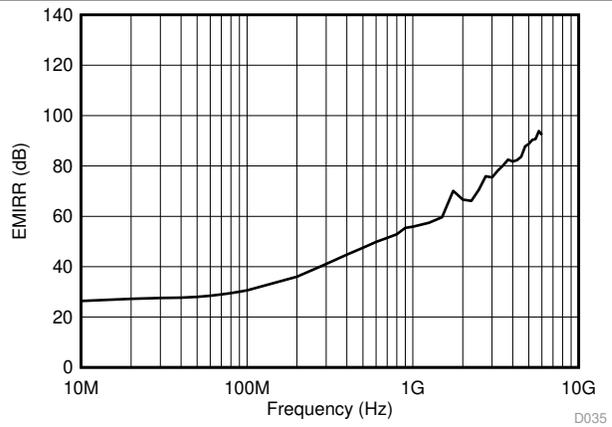


Figure 30. Electromagnetic Interference Rejection Ratio Referred to Noninverting Input (EMIRR+) vs Frequency

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_+ = 2.75\text{ V}$, $V_- = -2.75\text{ V}$, $R_L = 10\text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$ (unless otherwise noted)

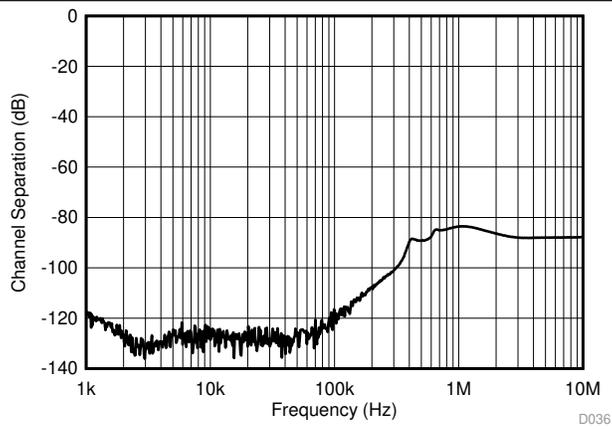


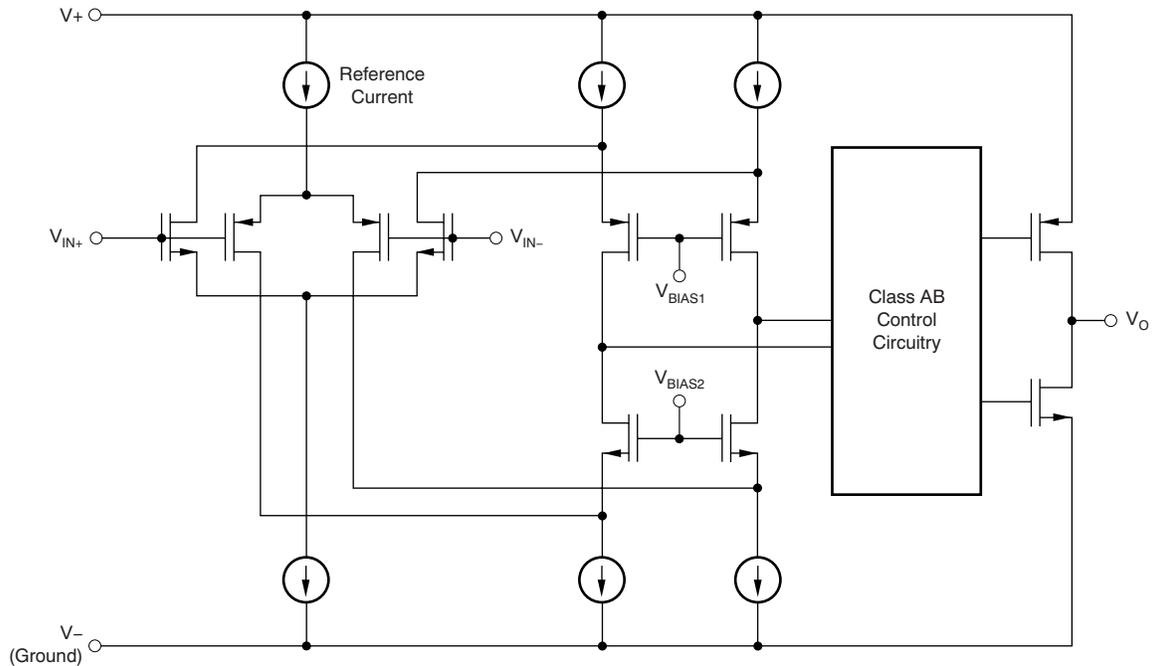
Figure 31. Channel Separation

7 Detailed Description

7.1 Overview

The LMV3xxA is a family of low-power, rail-to-rail output op amps. These devices operate from 2.5 V to 5.5 V, are unity-gain stable, and are designed for a wide range of general-purpose applications. The input common-mode voltage range includes the negative rail and allows the LMV3xxA family to be used in many single-supply applications. Rail-to-rail output swing significantly increases dynamic range, especially in low-supply applications, and makes them suitable for driving sampling analog-to-digital converters (ADCs).

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Operating Voltage

The LMV3xxA family of op amps are for operation from 2.5 V to 5.5 V. In addition, many specifications such as input offset voltage, quiescent current, offset current, and short circuit current apply from -40°C to 125°C . Parameters that vary significantly with operating voltages or temperature are shown in the [Typical Characteristics](#) section.

7.3.2 Input Common Mode Range

The input common-mode voltage range of the LMV3xxA family extends 100 mV beyond the negative supply rail and within 1 V below the positive rail for the full supply voltage range of 2.5 V to 5.5 V. This performance is achieved with a P-channel differential pair, as shown in the [Functional Block Diagram](#). Additionally, a complementary N-channel differential pair has been included in parallel to eliminate issues with phase reversal that are common with previous generations of op amps. However, the N-channel pair is not optimized for operation. TI recommends limiting any voltages applied at the inputs to less than $V_{\text{CC}} - 1\text{ V}$ to ensure that the op amp conforms to the specifications detailed in the [Electrical Characteristics](#) table.

7.3.3 Rail-to-Rail Output

Designed as a low-power, low-voltage operational amplifier, the LMV3xxA family delivers a robust output drive capability. A class-AB output stage with common-source transistors achieves full rail-to-rail output swing capability. For resistive loads of 10 k Ω , the output swings to within 20 mV of either supply rail, regardless of the applied power-supply voltage. Different load conditions change the ability of the amplifier to swing close to the rails.

7.3.4 Overload Recovery

Overload recovery is defined as the time required for the operational amplifier output to recover from a saturated state to a linear state. The output devices of the operational amplifier enter a saturation region when the output voltage exceeds the rated operating voltage, because of the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return to the linear state. After the charge carriers return to the linear state, the device begins to slew at the specified slew rate. Therefore, the propagation delay (in case of an overload condition) is the sum of the overload recovery time and the slew time. The overload recovery time for the LMV3xxA family is approximately 850 ns.

7.4 Device Functional Modes

The LMV3xxA family has a single functional mode. The devices are powered on as long as the power-supply voltage is between 2.5 V ($\pm 1.25\text{ V}$) and 5.5 V ($\pm 2.75\text{ V}$).

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LMV3xxA family of low-power, rail-to-rail output operational amplifiers is specifically designed for portable applications. The devices operate from 2.5 V to 5.5 V, are unity-gain stable, and are suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving less than or equal to 10-k Ω loads connected to any point between V+ and V-. The input common-mode voltage range includes the negative rail, and allows the LMV3xxA devices to be used in many single-supply applications.

8.2 Typical Application

8.2.1 LMV3xxA Low-Side, Current Sensing Application

Figure 32 shows the LMV3xxA configured in a low-side current sensing application.

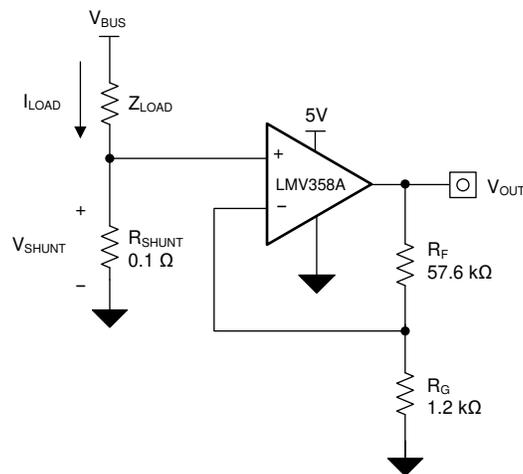


Figure 32. LMV3xxA in a Low-Side, Current-Sensing Application

Typical Application (continued)

8.2.1.1 Design Requirements

The design requirements for this design are:

- Load current: 0 A to 1 A
- Output voltage: 4.9 V
- Maximum shunt voltage: 100 mV

8.2.1.2 Detailed Design Procedure

The transfer function of the circuit in is given in [Equation 1](#).

$$V_{\text{OUT}} = I_{\text{LOAD}} \times R_{\text{SHUNT}} \times \text{Gain} \quad (1)$$

The load current (I_{LOAD}) produces a voltage drop across the shunt resistor (R_{SHUNT}). The load current is set from 0 A to 1 A. To keep the shunt voltage below 100 mV at maximum load current, the largest shunt resistor is shown using [Equation 2](#).

$$R_{\text{SHUNT}} = \frac{V_{\text{SHUNT_MAX}}}{I_{\text{LOAD_MAX}}} = \frac{100\text{mV}}{1\text{A}} = 100\text{m}\Omega \quad (2)$$

Using [Equation 2](#), R_{SHUNT} is calculated to be 100 m Ω . The voltage drop produced by I_{LOAD} and R_{SHUNT} is amplified by the LMV3xxA to produce an output voltage of approximately 0 V to 4.9 V. The gain needed by the LMV3xxA to produce the necessary output voltage is calculated using [Equation 3](#).

$$\text{Gain} = \frac{(V_{\text{OUT_MAX}} - V_{\text{OUT_MIN}})}{(V_{\text{IN_MAX}} - V_{\text{IN_MIN}})} \quad (3)$$

Using [Equation 3](#), the required gain is calculated to be 49 V/V, which is set with resistors R_{F} and R_{G} . [Equation 4](#) sizes the resistors R_{F} and R_{G} , to set the gain of the LMV3xxA to 49 V/V.

$$\text{Gain} = 1 + \frac{(R_{\text{F}})}{(R_{\text{G}})} \quad (4)$$

Selecting R_{F} as 57.6 k Ω and R_{G} as 1.2 k Ω provides a combination that equals 49 V/V. [Figure 33](#) shows the measured transfer function of the circuit shown in [Figure 32](#). Notice that the gain is only a function of the feedback and gain resistors. This gain is adjusted by varying the ratio of the resistors and the actual resistors values are determined by the impedance levels that the designer wants to establish. The impedance level determines the current drain, the effect that stray capacitance has, and a few other behaviors. There is no optimal impedance selection that works for every system, you must choose an impedance that is ideal for your system parameters.

8.2.1.3 Application Curve

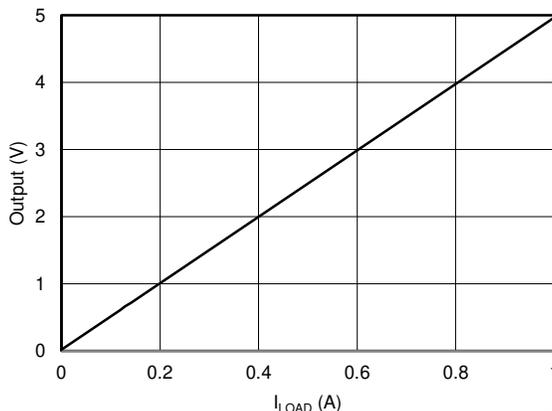


Figure 33. Low-Side, Current-Sense Transfer Function

Typical Application (continued)

8.2.2 Single-Supply Photodiode Amplifier

Photodiodes are used in many applications to convert light signals to electrical signals. The current through the photodiode is proportional to the photon energy absorbed, and is commonly in the range of a few hundred picoamps to a few tens of microamps. An amplifier in a transimpedance configuration is typically used to convert the low-level photodiode current to a voltage signal for processing in an MCU. The circuit shown in Figure 34 is an example of a single-supply photodiode amplifier circuit using the LMV358A.

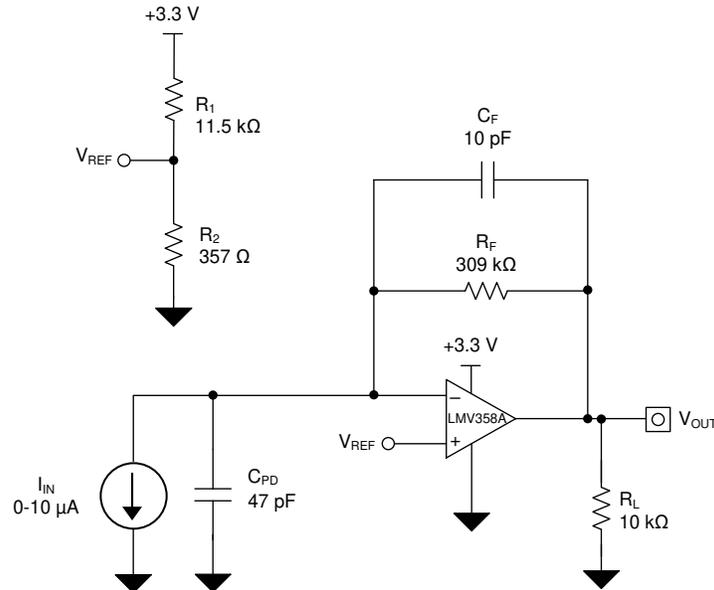


Figure 34. Single-Supply Photodiode Amplifier Circuit

Typical Application (continued)

8.2.2.1 Design Requirements

The design requirements for this design are:

- Supply voltage: 3.3 V
- Input: 0 μ A to 10 μ A
- Output: 0.1 V to 3.2 V
- Bandwidth: 50 kHz

8.2.2.2 Detailed Design Procedure

The transfer function between the output voltage (V_{OUT}), the input current, (I_{IN}) and the reference voltage (V_{REF}) is defined in [Equation 5](#).

$$V_{OUT} = I_{IN} \times R_F + V_{REF} \quad (5)$$

Where:

$$V_{REF} = V_+ \times \left(\frac{R_1 \times R_2}{R_1 + R_2} \right) \quad (6)$$

Set V_{REF} to 100 mV to meet the minimum output voltage level by setting R1 and R2 to meet the required ratio calculated in [Equation 7](#).

$$\frac{V_{REF}}{V_+} = \frac{0.1 \text{ V}}{3.3 \text{ V}} = 0.0303 \quad (7)$$

The closest resistor ratio to meet this ratio sets R1 to 11.5 k Ω and R2 to 357 Ω .

The required feedback resistance can be calculated based on the input current and desired output voltage.

$$R_F = \frac{V_{OUT} - V_{REF}}{I_{IN}} = \frac{3.2 \text{ V} - 0.1 \text{ V}}{10 \mu\text{A}} = 310 \frac{\text{kV}}{\text{A}} \approx 309 \text{ k}\Omega \quad (8)$$

Calculate the value for the feedback capacitor based on R_F and the desired –3-dB bandwidth, (f_{-3dB}) using [Equation 9](#).

$$C_F = \frac{1}{2 \times \pi \times R_F \times f_{-3dB}} = \frac{1}{2 \times \pi \times 309 \text{ k}\Omega \times 50 \text{ kHz}} = 10.3 \text{ pF} \approx 10 \text{ pF} \quad (9)$$

The minimum op amp bandwidth required for this application is based on the value of R_F , C_F , and the capacitance on the INx– pin of the LMV358A which is equal to the sum of the photodiode shunt capacitance, (CPD) the common-mode input capacitance, (CCM) and the differential input capacitance (CD) as [Equation 10](#) shows.

$$C_{IN} = C_{PD} + C_{CM} + C_D = 47 \text{ pF} + 5 \text{ pF} + 1 \text{ pF} = 53 \text{ pF} \quad (10)$$

The minimum op amp bandwidth is calculated in [Equation 11](#).

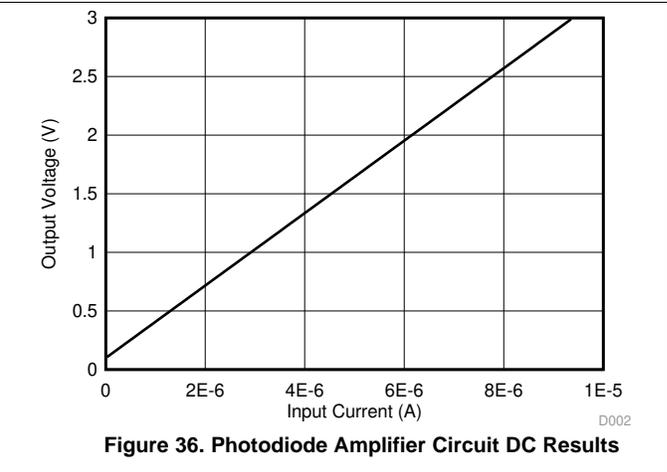
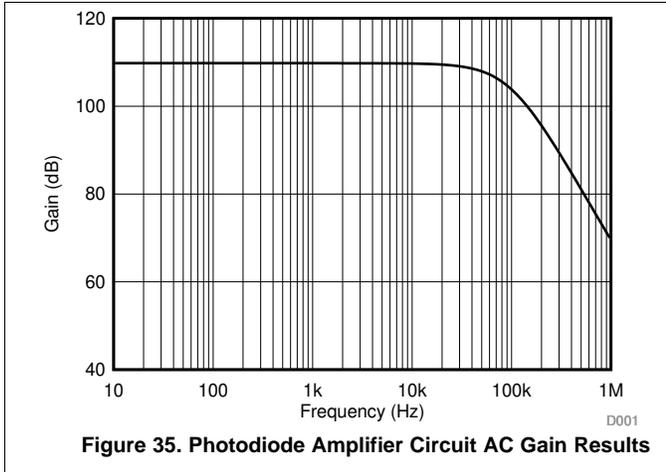
$$f_{-BGW} \geq \frac{C_{IN} + C_F}{2 \times \pi \times R_F \times C_F^2} \geq 324 \text{ kHz} \quad (11)$$

The 1-MHz bandwidth of the LMV3xxA meets the minimum bandwidth requirement and remains stable in this application configuration.

Typical Application (continued)

8.2.2.3 Application Curves

The measured current-to-voltage transfer function for the photodiode amplifier circuit is shown in [Figure 35](#). The measured performance of the photodiode amplifier circuit is shown in [Figure 36](#).



9 Power Supply Recommendations

The LMV3xxA family is specified for operation from 2.5 V to 5.5 V (± 1.25 V to ± 2.75 V); many specifications apply from -40°C to 125°C . The [Typical Characteristics](#) section presents parameters that may exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 6 V may permanently damage the device; see the [Absolute Maximum Ratings](#) table.

Place 0.1- μF bypass capacitors close to the power-supply pins to reduce coupling errors from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see the [Layout Guidelines](#) section.

9.1 Input and ESD Protection

The LMV3xxA family incorporates internal ESD protection circuits on all pins. For input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes provide in-circuit, input overdrive protection, as long as the current is limited to 10 mA. [Figure 37](#) shows how a series input resistor can be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value must be kept to a minimum in noise-sensitive applications.

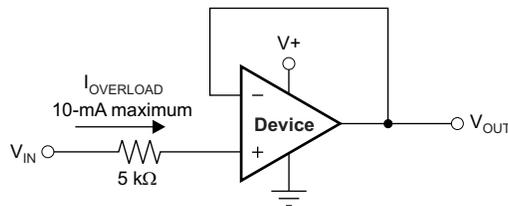


Figure 37. Input Current Protection

10 Layout

10.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power connections of the board and propagate to the power pins of the op amp itself. Bypass capacitors are used to reduce the coupled noise by providing a low-impedance path to ground.
 - Connect low-ESR, 0.1- μ F ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is adequate for single-supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise pickup. Take care to physically separate digital and analog grounds, paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace at a 90 degree angle is much better as opposed to running the traces in parallel with the noisy trace.
- Place the external components as close to the device as possible, as shown in [Figure 39](#). Keeping R_F and R_G close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring may significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit can experience performance shifts resulting from moisture ingress into the plastic package. Following any aqueous PCB cleaning process, baking the PCB assembly is recommended to remove moisture introduced into the device packaging during the cleaning process. A low-temperature, post-cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

10.2 Layout Example

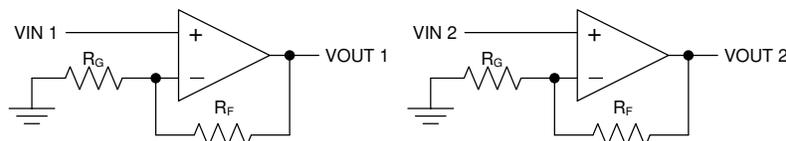


Figure 38. Schematic Representation for [Figure 39](#)

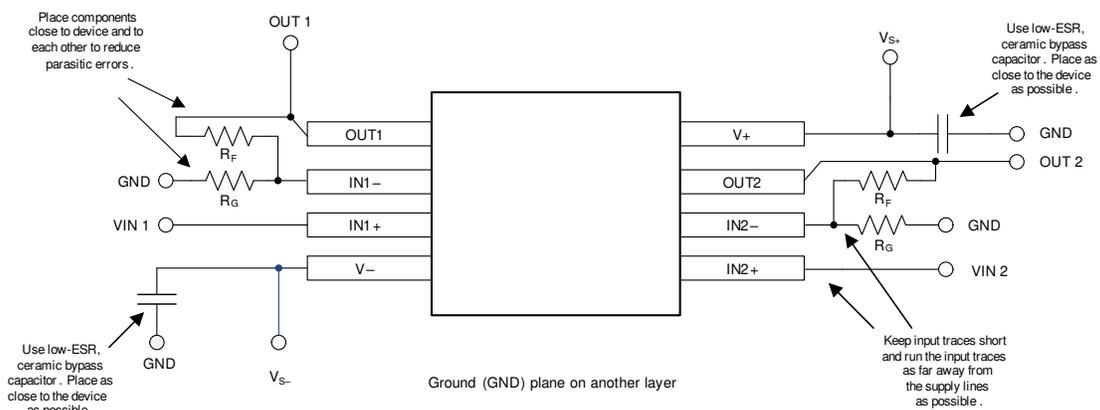


Figure 39. Layout Example

11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [EMI Rejection Ratio of Operational Amplifiers](#)

11.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 1. Related Links

| PARTS | PRODUCT FOLDER | ORDER NOW | TECHNICAL DOCUMENTS | TOOLS & SOFTWARE | SUPPORT & COMMUNITY |
|---------|----------------------------|----------------------------|----------------------------|----------------------------|----------------------------|
| LMV321A | Click here |
| LMV358A | Click here |
| LMV324A | Click here |

11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.4 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

11.5 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| LMV321AIDBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 1OIF | Samples |
| LMV321AIDCKR | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU SN | Level-2-260C-1 YEAR | -40 to 125 | 1C2 | Samples |
| LMV321AUIDBVR | PREVIEW | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 1WOF | |
| LMV324AIDR | ACTIVE | SOIC | D | 14 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | LMV324 | Samples |
| LMV324AIPWR | ACTIVE | TSSOP | PW | 14 | 2000 | Green (RoHS & no Sb/Br) | CU SN | Level-2-260C-1 YEAR | -40 to 125 | LMV324A | Samples |
| LMV358AIDDFR | ACTIVE | SOT-23-THIN | DDF | 8 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 358A | Samples |
| LMV358AIDGKR | ACTIVE | VSSOP | DGK | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAUAG | Level-2-260C-1 YEAR | -40 to 125 | 1MAX | Samples |
| LMV358AIDGKT | ACTIVE | VSSOP | DGK | 8 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAUAG | Level-2-260C-1 YEAR | -40 to 125 | 1MAX | Samples |
| LMV358AIDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU SN | Level-2-260C-1 YEAR | -40 to 125 | MV358A | Samples |
| LMV358AIPWR | ACTIVE | TSSOP | PW | 8 | 2000 | Green (RoHS & no Sb/Br) | CU SN | Level-2-260C-1 YEAR | -40 to 125 | LMV358 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

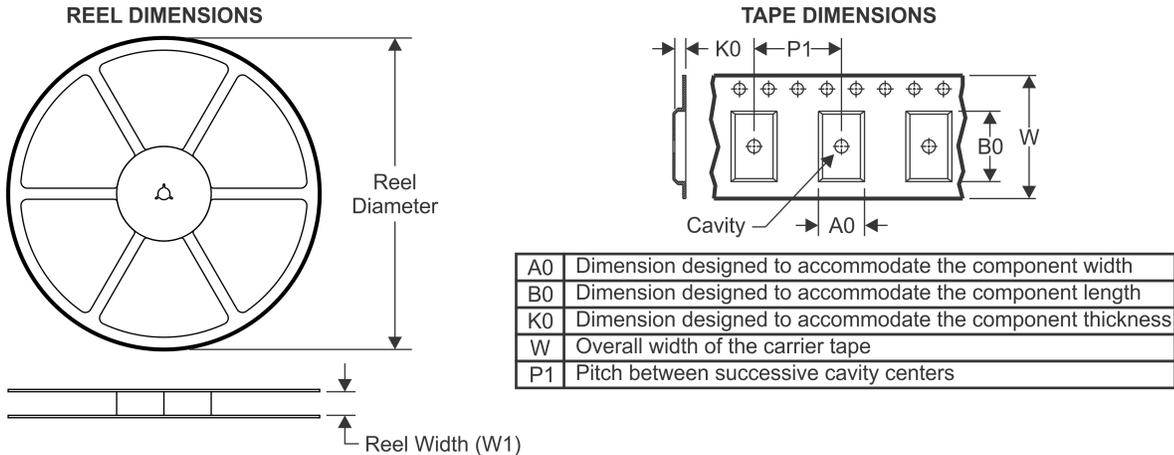
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

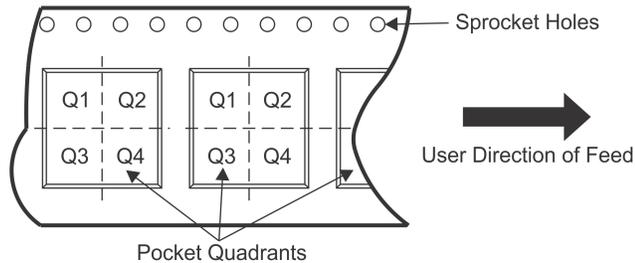
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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

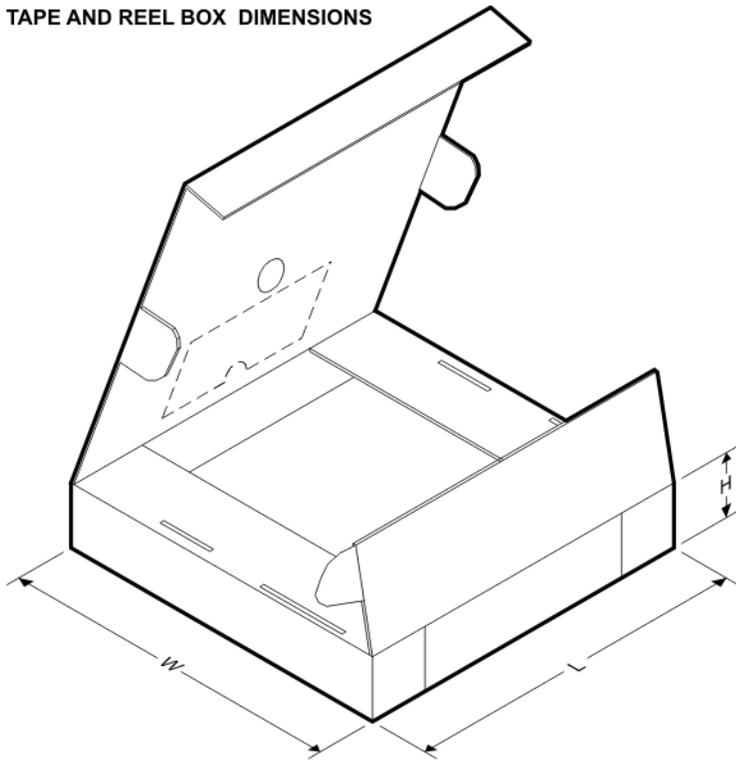


QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LMV321AIDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| LMV321AIDCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| LMV324AIDR | SOIC | D | 14 | 2500 | 330.0 | 15.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LMV324AIPWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LMV358AIDDFR | SOT-23-THIN | DDF | 8 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| LMV358AIDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LMV358AIDGKT | VSSOP | DGK | 8 | 250 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LMV358AIDR | SOIC | D | 8 | 2500 | 330.0 | 15.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LMV358AIPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LMV321AIDBVR | SOT-23 | DBV | 5 | 3000 | 210.0 | 185.0 | 35.0 |
| LMV321AIDCKR | SC70 | DCK | 5 | 3000 | 190.0 | 190.0 | 30.0 |
| LMV324AIDR | SOIC | D | 14 | 2500 | 336.6 | 336.6 | 41.3 |
| LMV324AIPWR | TSSOP | PW | 14 | 2000 | 366.0 | 364.0 | 50.0 |
| LMV358AIDDFR | SOT-23-THIN | DDF | 8 | 3000 | 210.0 | 185.0 | 35.0 |
| LMV358AIDGKR | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| LMV358AIDGKT | VSSOP | DGK | 8 | 250 | 366.0 | 364.0 | 50.0 |
| LMV358AIDR | SOIC | D | 8 | 2500 | 336.6 | 336.6 | 41.3 |
| LMV358AIPWR | TSSOP | PW | 8 | 2000 | 366.0 | 364.0 | 50.0 |

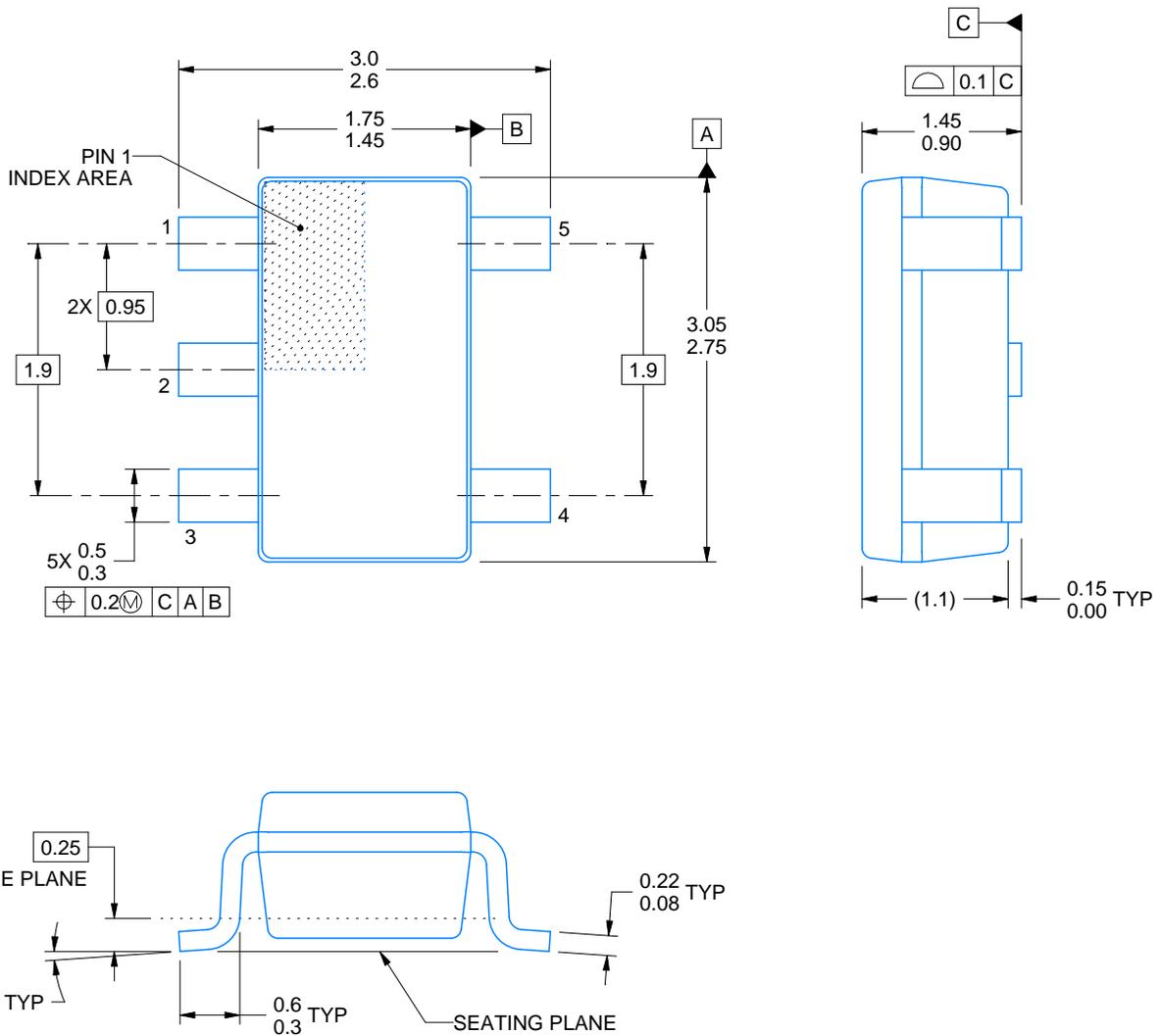


DBV0005A

PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214839/E 09/2019

NOTES:

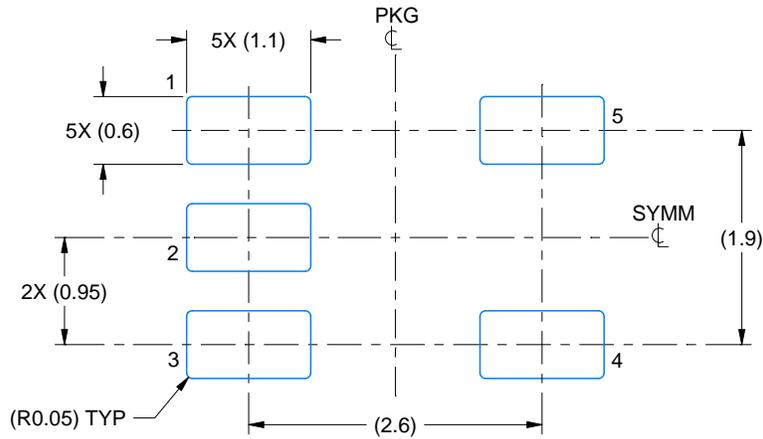
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

EXAMPLE BOARD LAYOUT

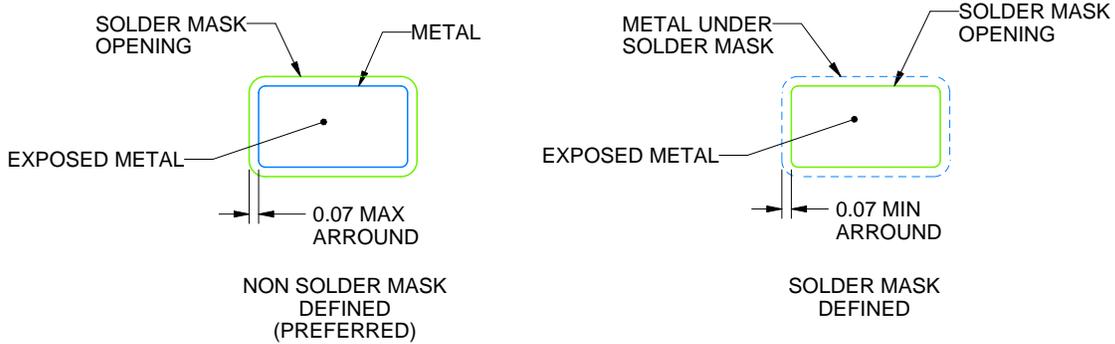
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/E 09/2019

NOTES: (continued)

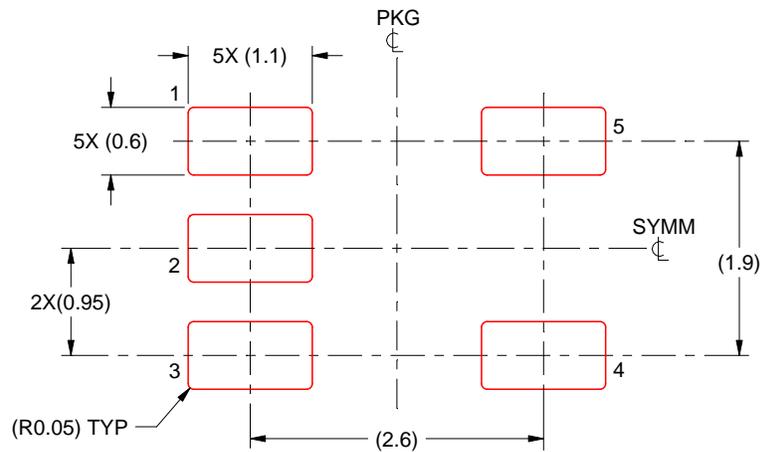
- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

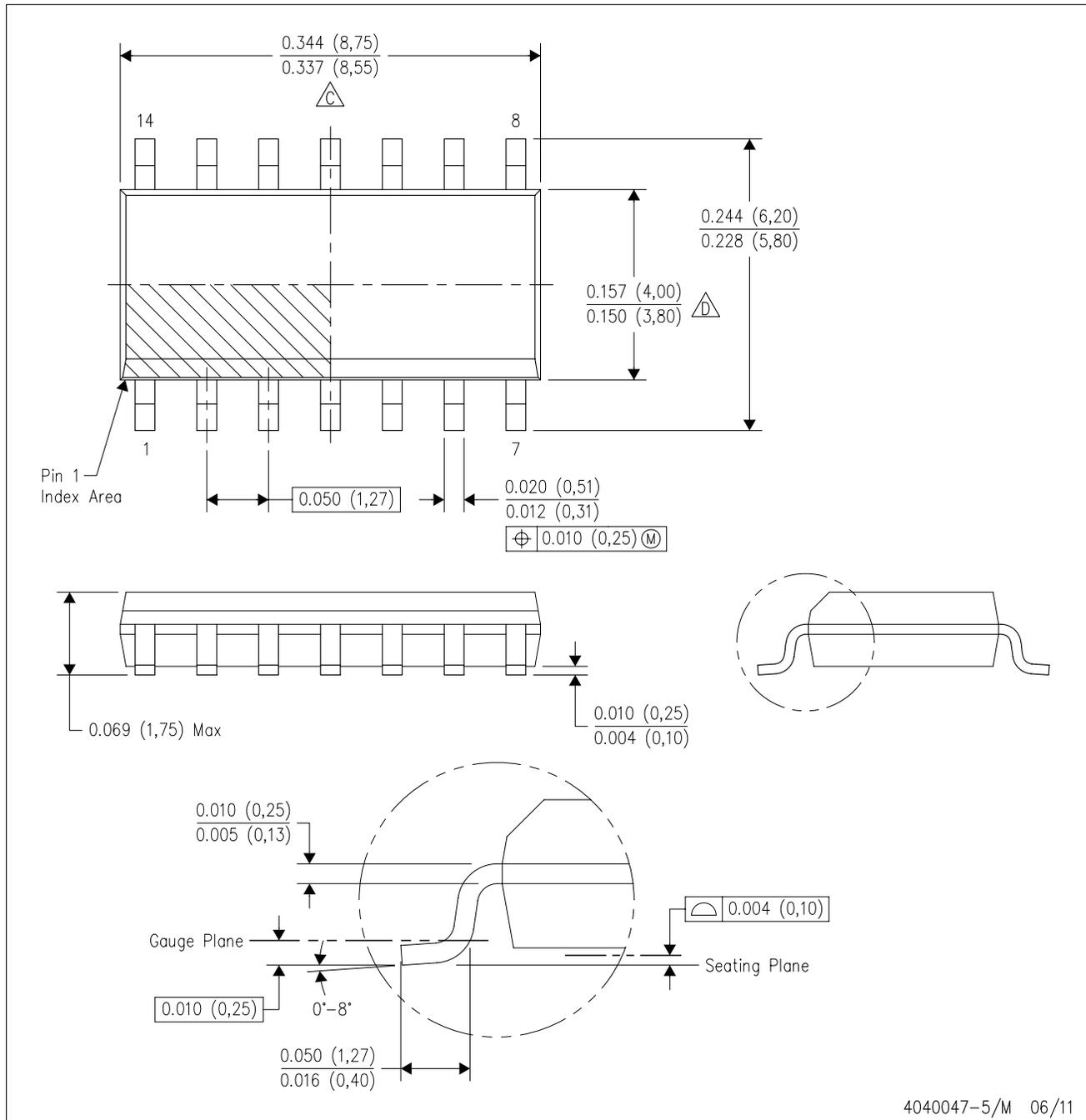
4214839/E 09/2019

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE

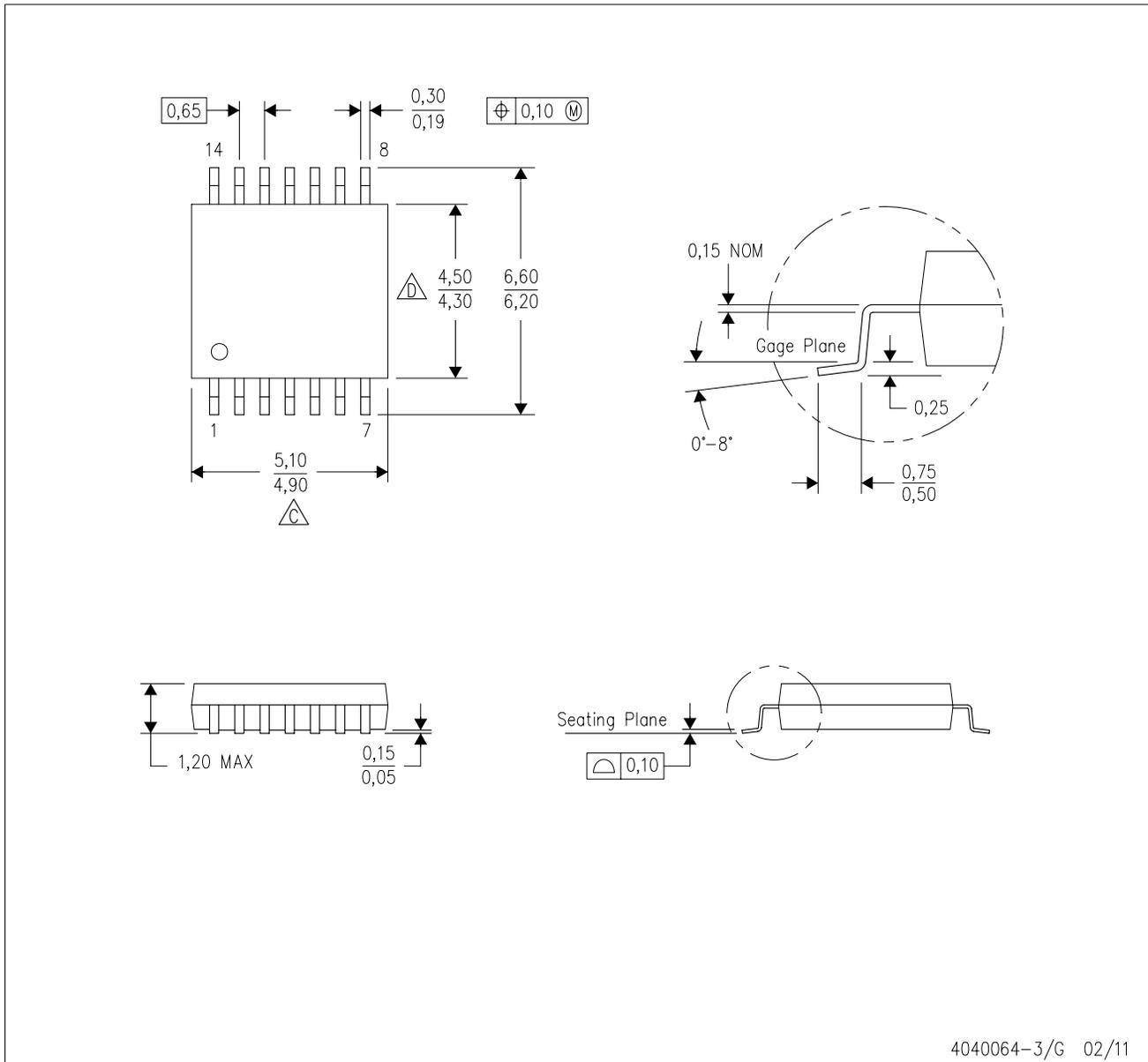


4040047-5/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AB.

PW (R-PDSO-G14)

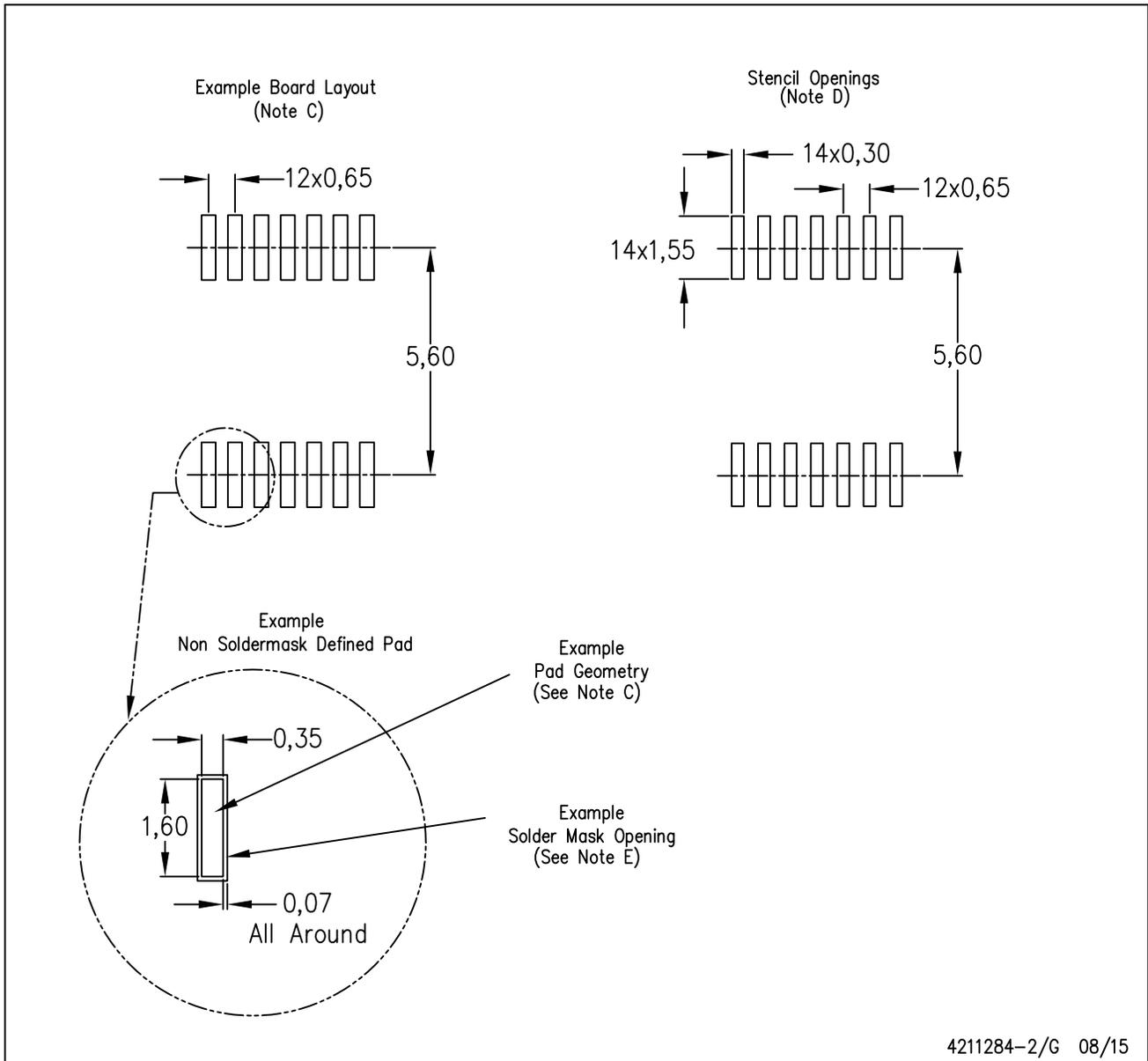
PLASTIC SMALL OUTLINE



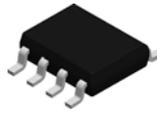
- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

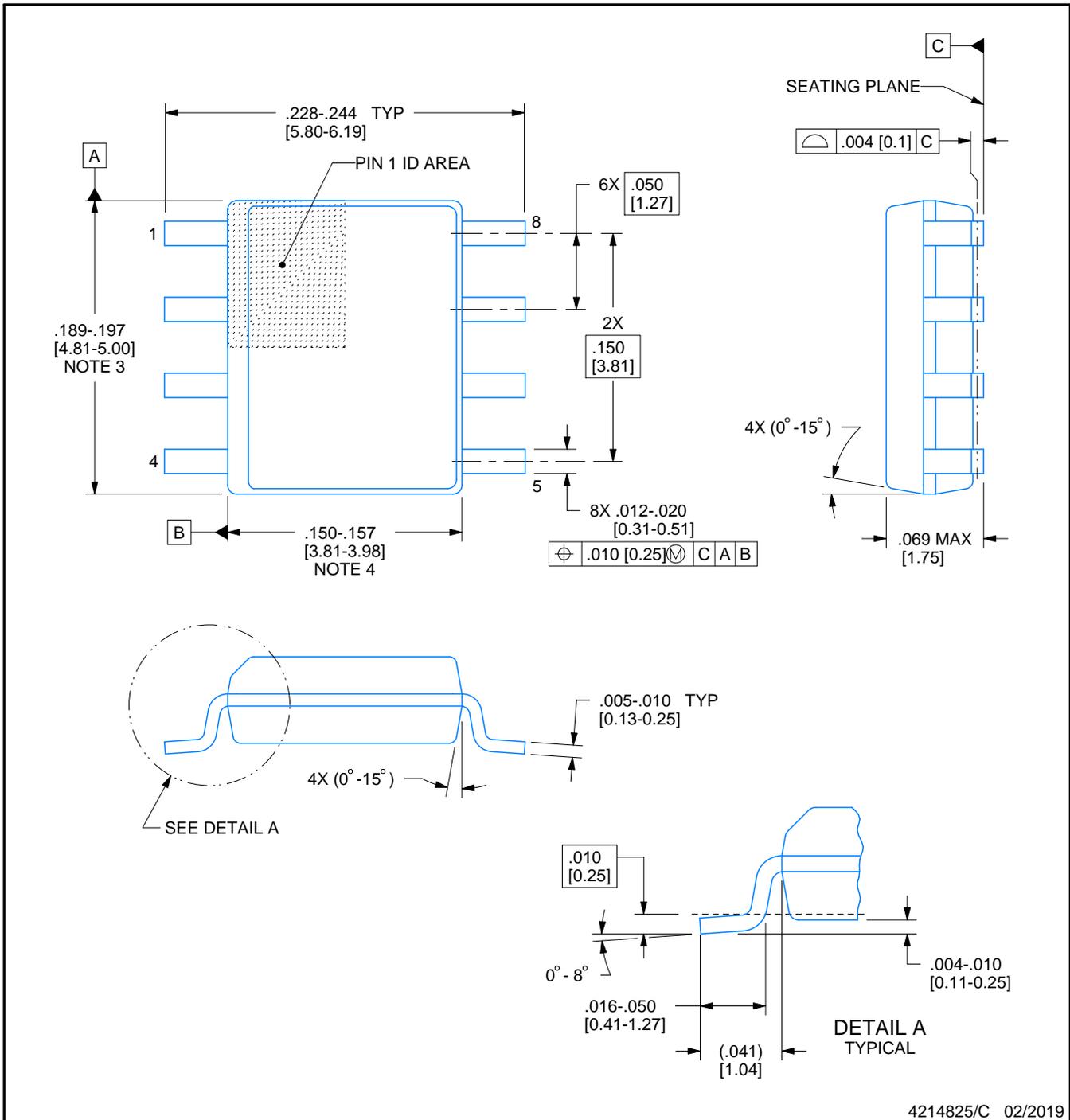


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

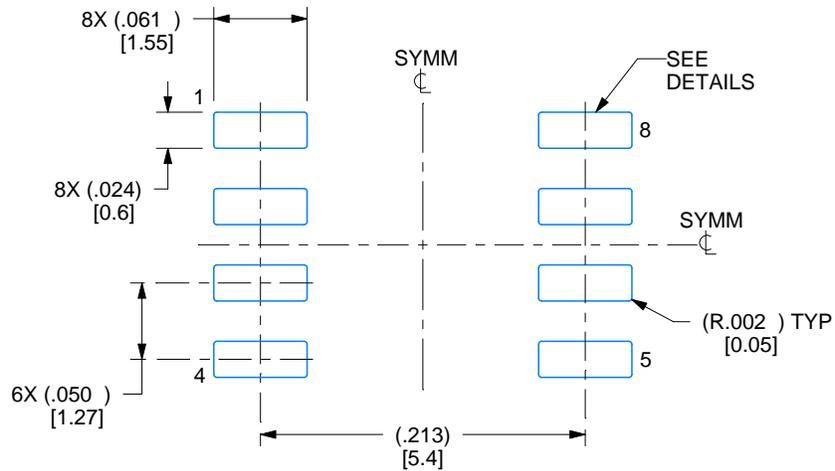
- Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
- This dimension does not include interlead flash.
- Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

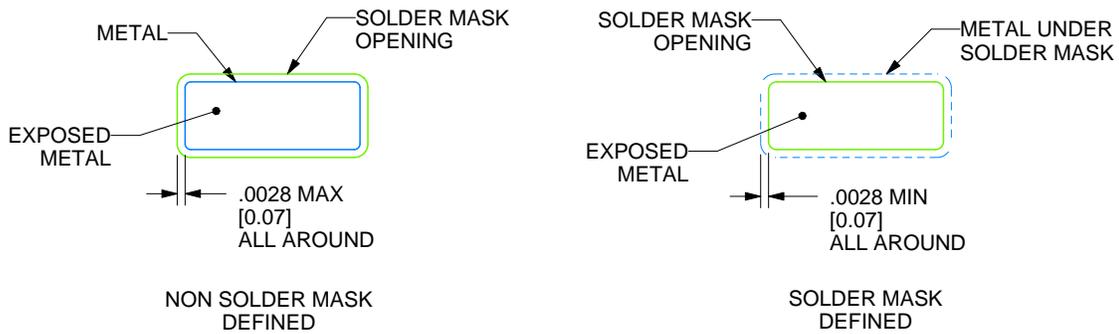
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

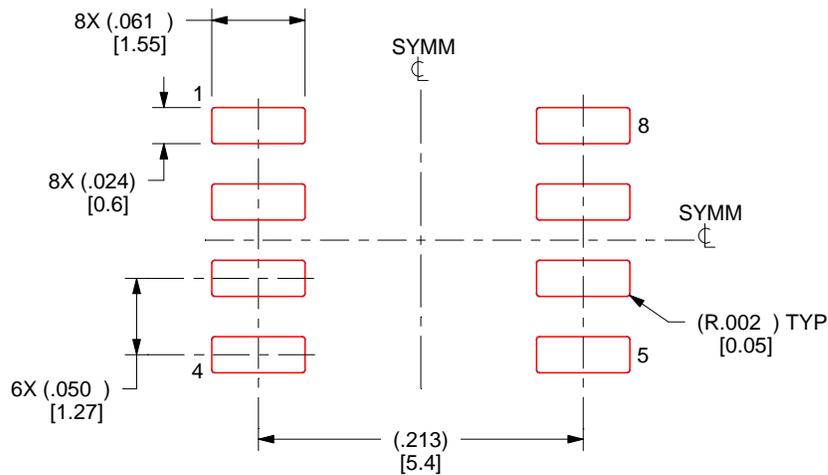
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

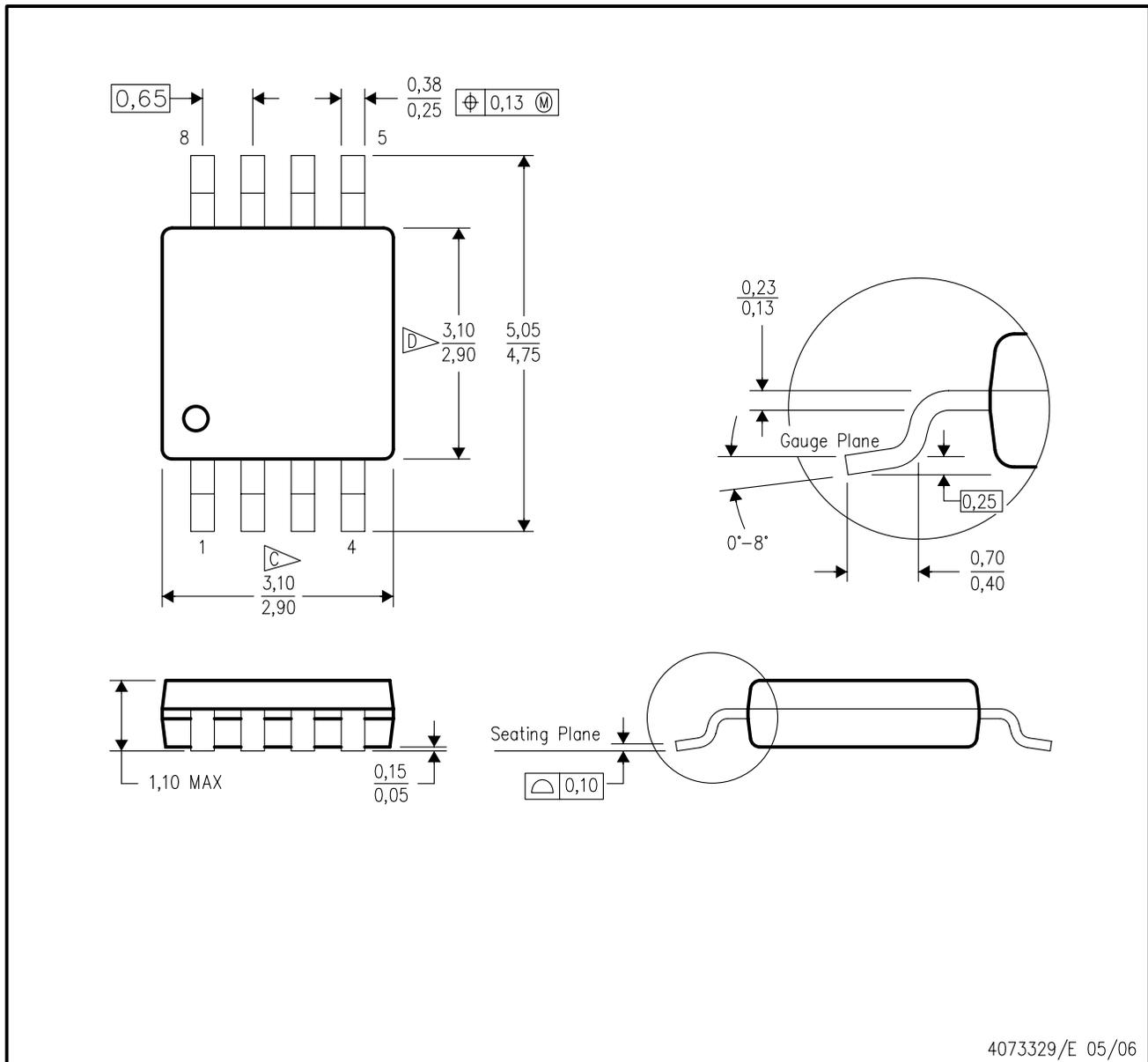
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

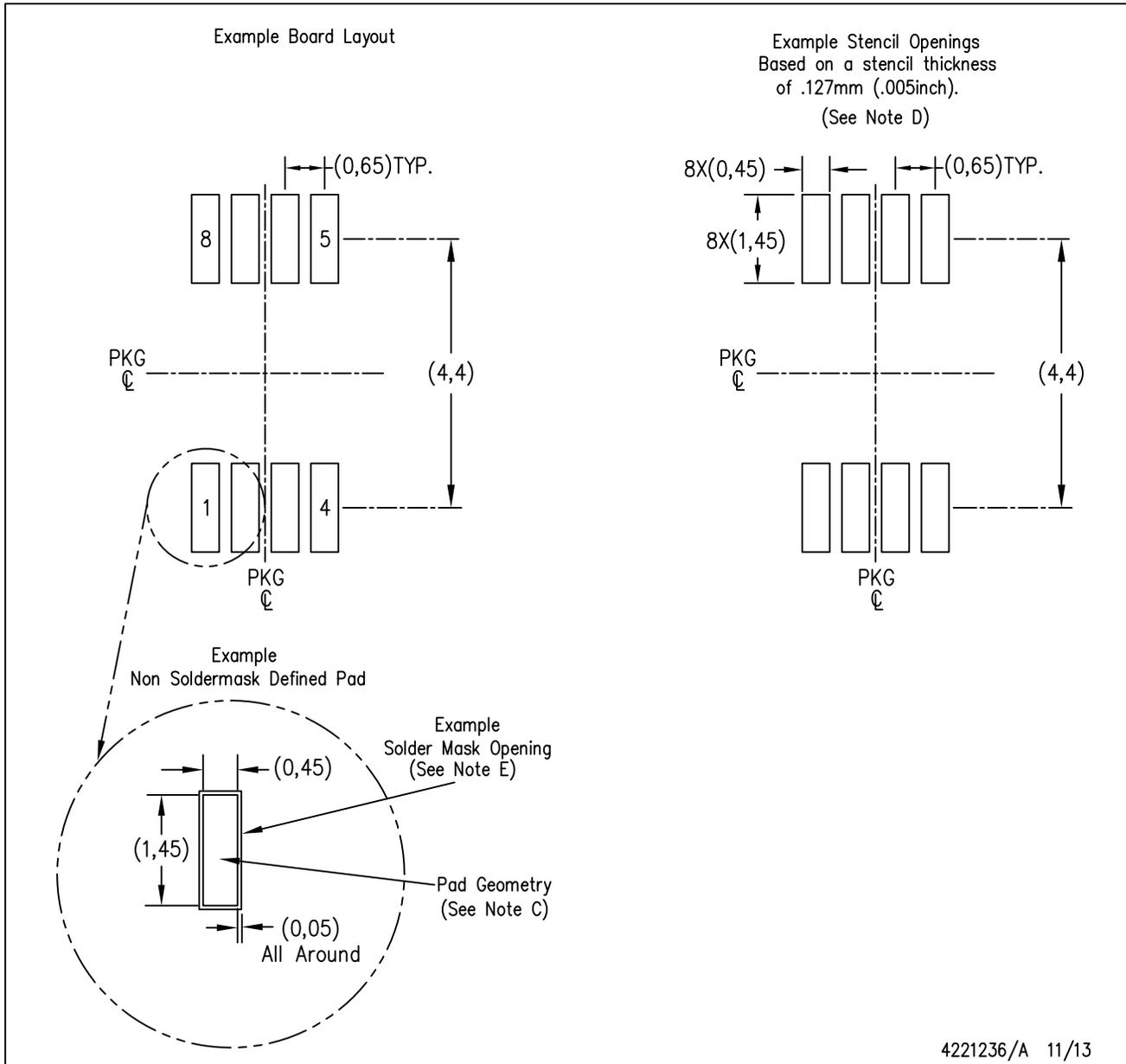
DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



4073329/E 05/06

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
 - E. Falls within JEDEC MO-187 variation AA, except interlead flash.



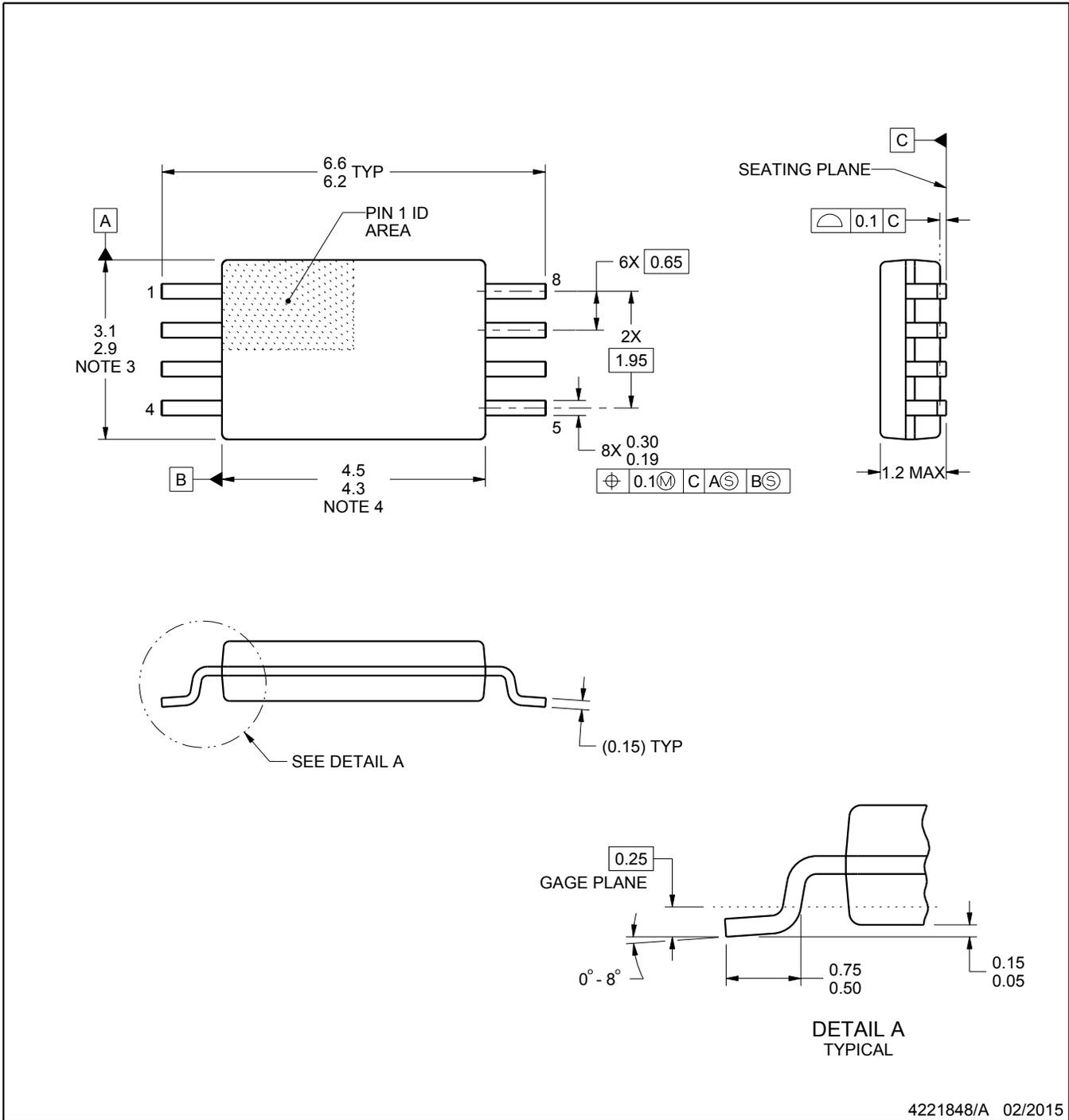
- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW0008A



PACKAGE OUTLINE
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

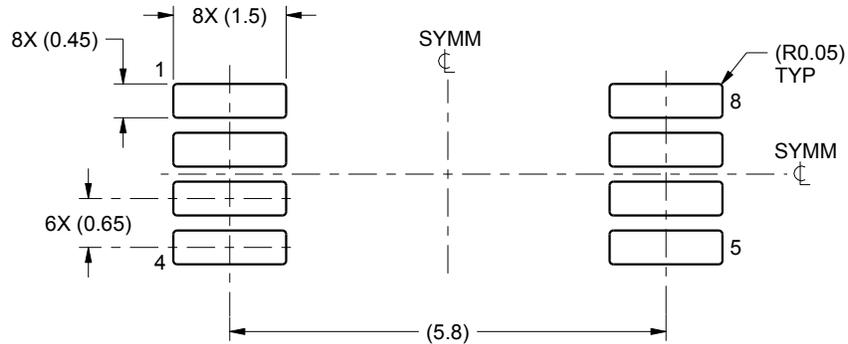
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153, variation AA.

EXAMPLE BOARD LAYOUT

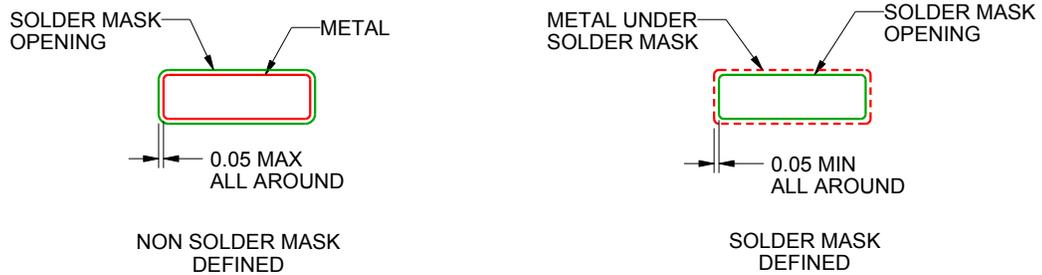
PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

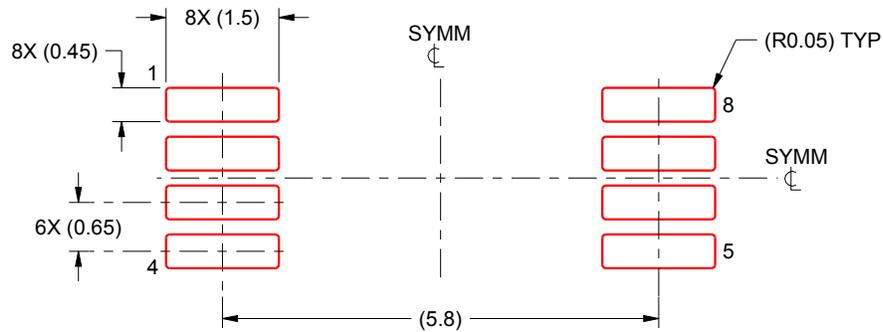
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

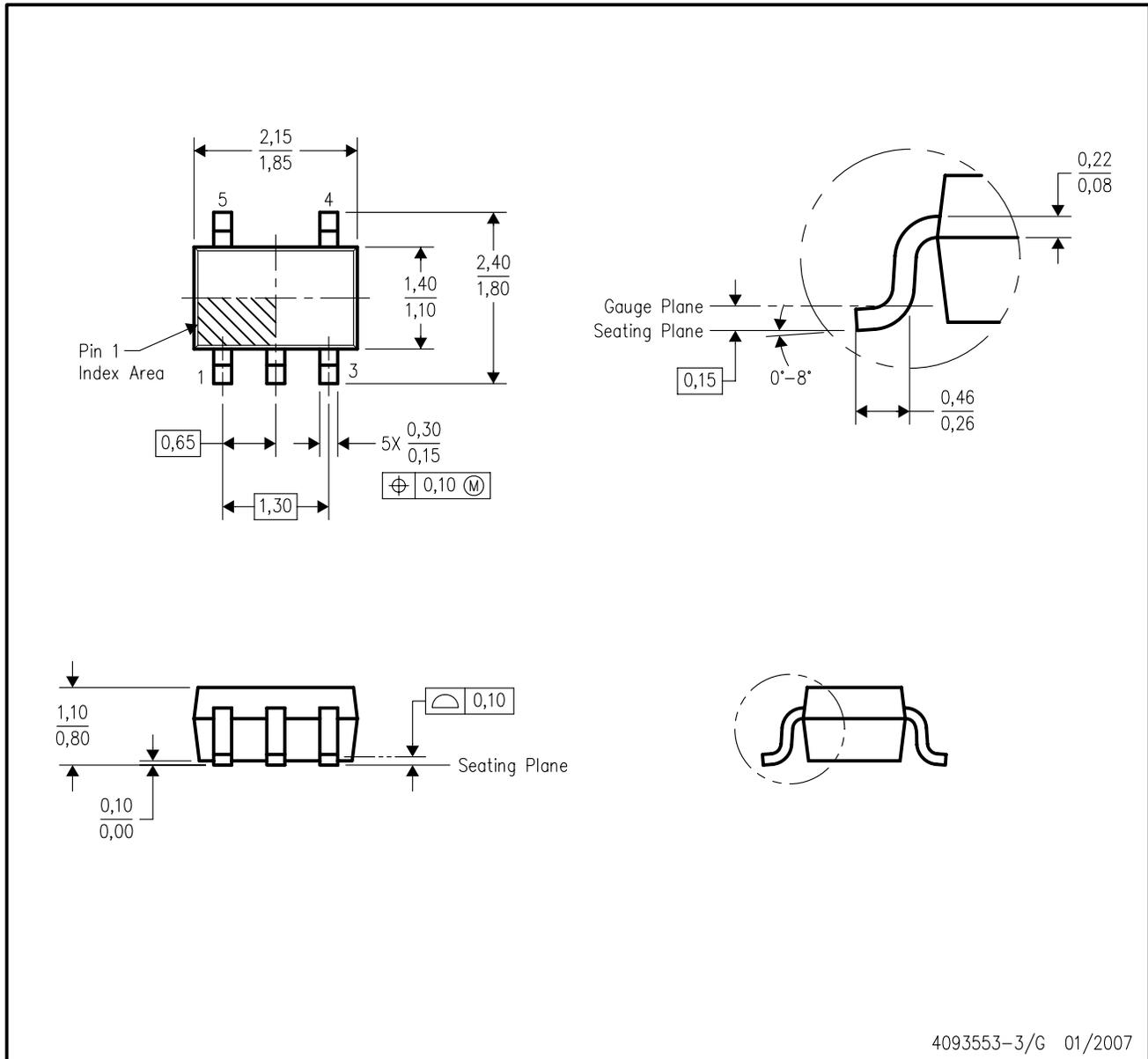
4221848/A 02/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DCK (R-PDSO-G5)

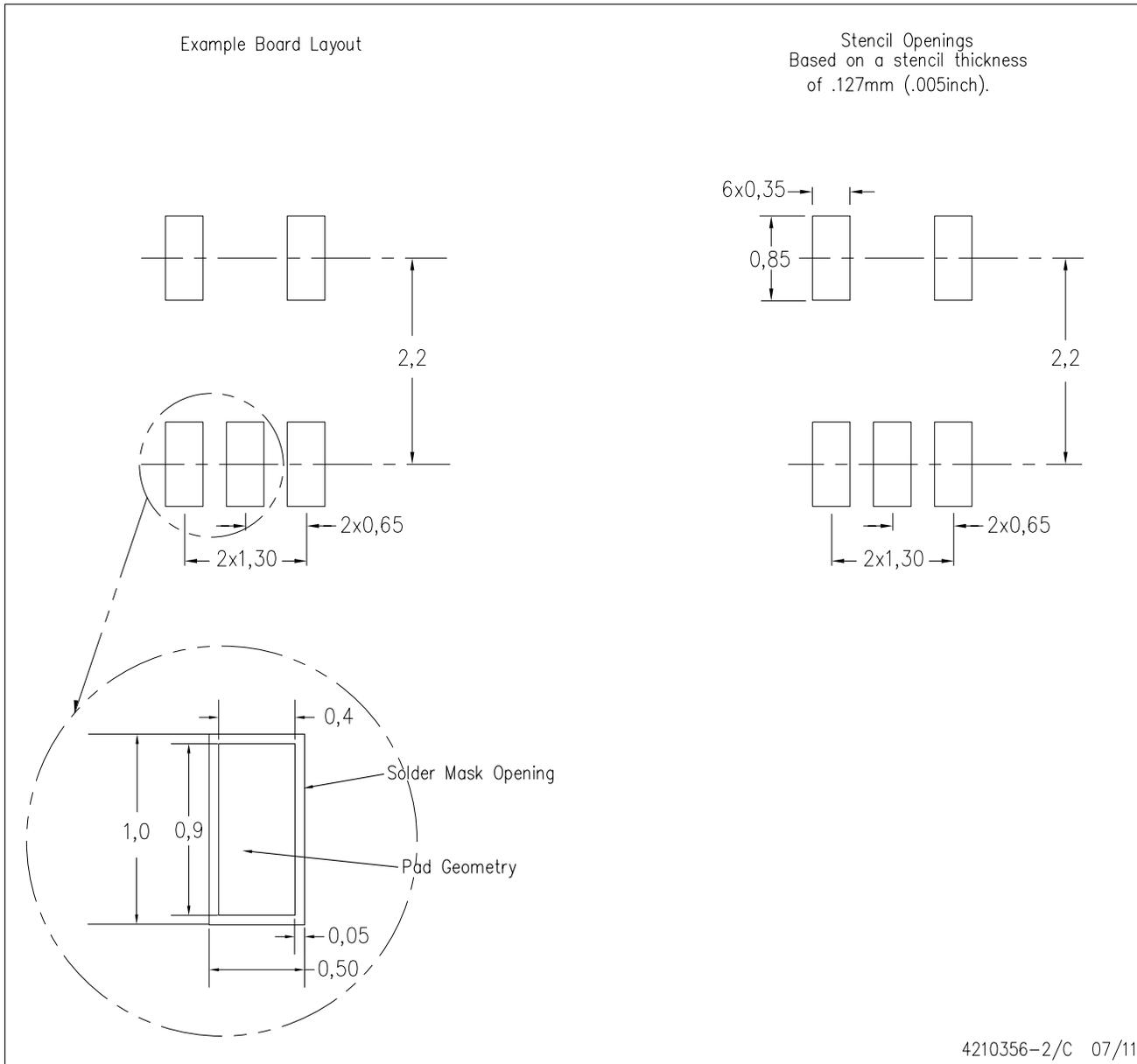
PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.

DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

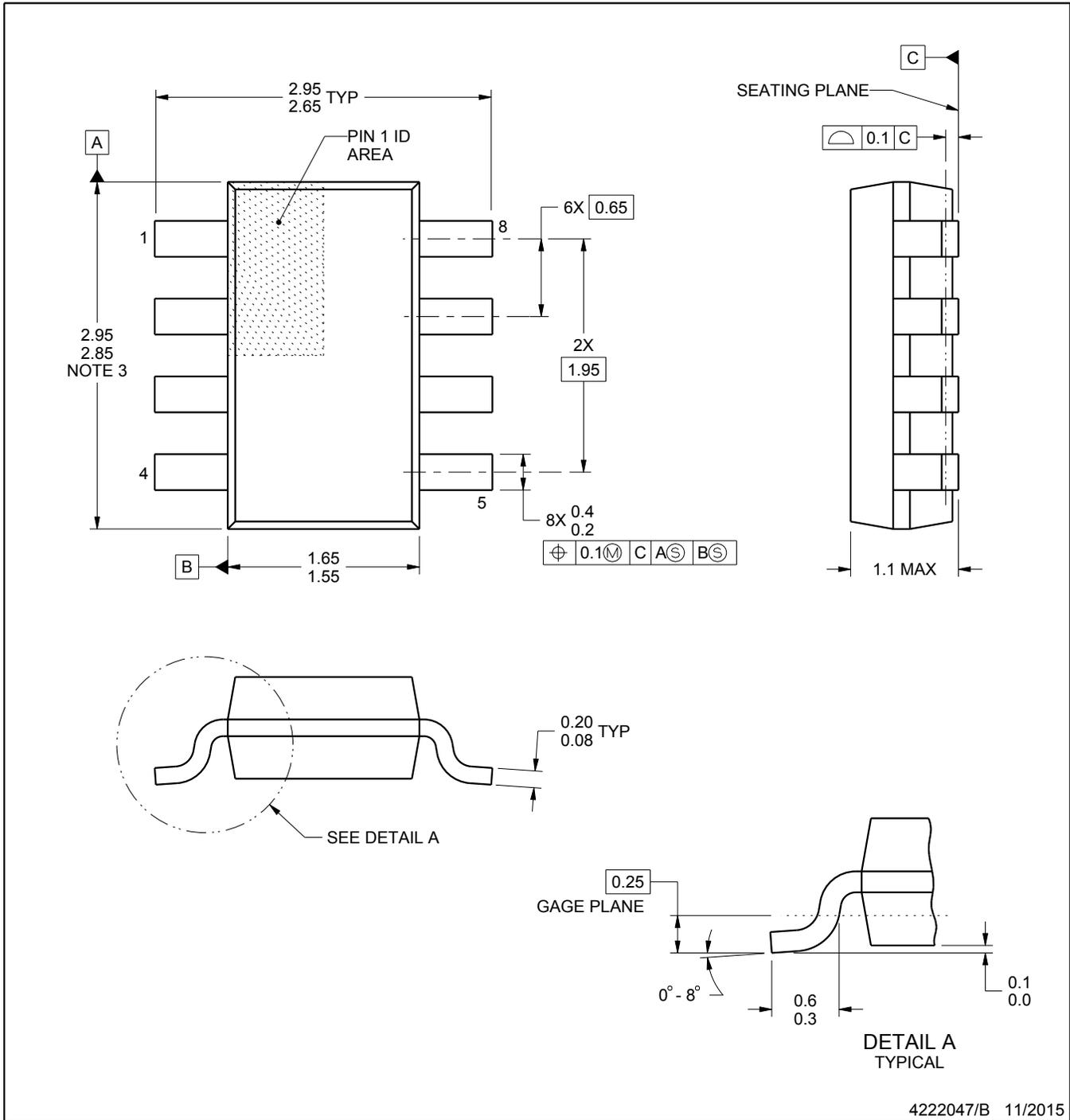
DDF0008A



PACKAGE OUTLINE

SOT-23 - 1.1 mm max height

PLASTIC SMALL OUTLINE



NOTES:

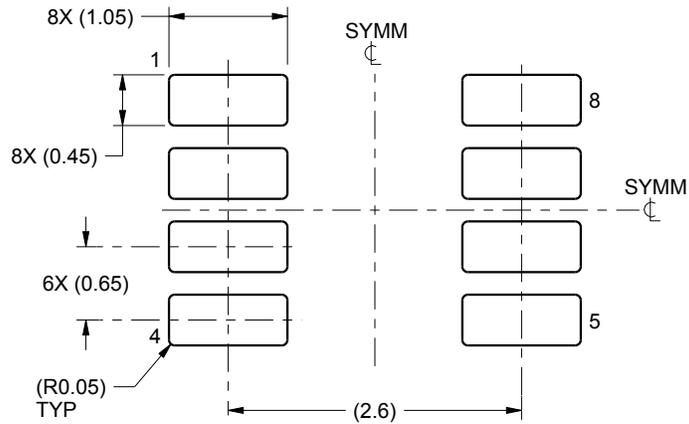
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

EXAMPLE BOARD LAYOUT

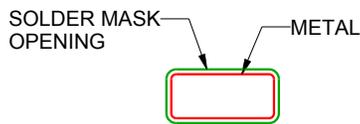
DDF0008A

SOT-23 - 1.1 mm max height

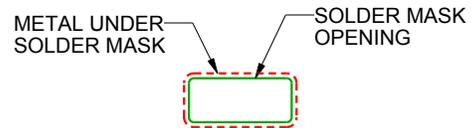
PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
SCALE:15X



NON SOLDER MASK
DEFINED



SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4222047/B 11/2015

NOTES: (continued)

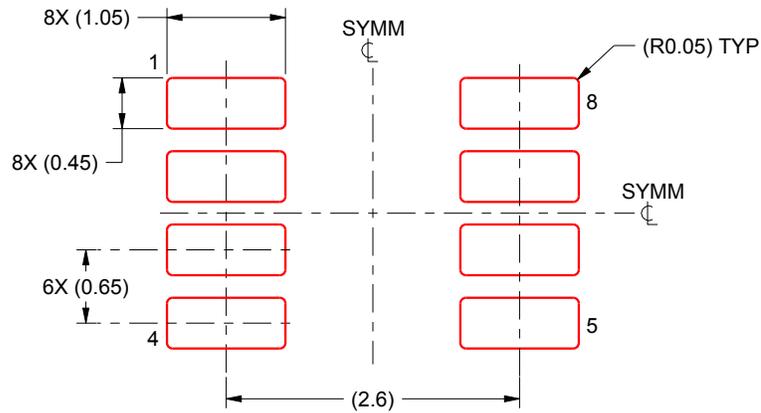
4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DDF0008A

SOT-23 - 1.1 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4222047/B 11/2015

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

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